

OPAx192-Q1 36-V Precision, Rail-to-Rail Input/Output, Low-Offset Voltage, Low-Input Bias Current Op Amp With e-trim™

1 Features

- Qualified for Automotive Applications
- AEC-Q100 Qualified with the Following Results:
 - Device Temperature Grade 1: -40°C to $+125^{\circ}\text{C}$ Ambient Operating Temperature
 - Device HBM ESD Classification Level 3A
 - Device CDM ESD Classification Level 4A
- Low Offset Voltage: $\pm 5\ \mu\text{V}$
- Low Offset Voltage Drift: $\pm 0.2\ \mu\text{V}/^{\circ}\text{C}$
- Low Noise: $5.5\ \text{nV}/\sqrt{\text{Hz}}$ at 1 kHz
- High Common-Mode Rejection: 140 dB
- Low Bias Current: $\pm 5\ \text{pA}$
- Rail-to-Rail Input and Output
- Wide Bandwidth: 10 MHz GBW
- High Slew Rate: 20 V/ μs
- Low Quiescent Current: 1 mA per Amplifier
- Wide Supply: $\pm 2.25\ \text{V}$ to $\pm 18\ \text{V}$, 4.5 V to 36 V
- EMI/RFI Filtered Inputs
- Differential Input Voltage Range to Supply Rail
- High Capacitive-Load-Drive Capability: 1 nF
- Industry-Standard Package:
 - Single and Dual Channel in VSSOP-8

2 Applications

- Motor Control for Automotive
- Traction Inverter
- On-Board Charger
- Precision Current Sensing

3 Description

The OPAx192-Q1 family (OPA192-Q1 and OPA2192-Q1) is a new generation of 36-V, e-trim operational amplifiers. The OPAx192-Q1 family of operational amplifiers use e-trim™, a method of package-level trim for offset and offset temperature drift implemented during the final steps of manufacturing after the plastic molding process. This method minimizes the influence of inherent input transistor mismatch, as well as errors induced during package molding.

These devices offer outstanding dc precision and ac performance, including rail-to-rail input/output, low offset ($\pm 5\ \mu\text{V}$, typical), low offset drift ($\pm 0.2\ \mu\text{V}/^{\circ}\text{C}$, typical), and 10-MHz bandwidth.

Unique features such as differential input-voltage range to the supply rail, high output current ($\pm 65\ \text{mA}$), high capacitive-load drive of up to 1 nF, and high slew rate (20 V/ μs) make the OPAx192-Q1 a robust, high-performance operational amplifier for high-voltage industrial applications.

The OPAx192-Q1 family of op amps is available in an 8-pin VSSOP package and is specified from -40°C to $+125^{\circ}\text{C}$.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|-----------|-------------------|
| OPA192-Q1 | VSSOP (8) | 3.00 mm x 3.00 mm |
| OPA2192-Q1 | | |

(1) For all available packages, see the package option addendum at the end of the data sheet.

OPAx192-Q1 Maintains Ultra-Low Input Offset Voltage Over Temperature

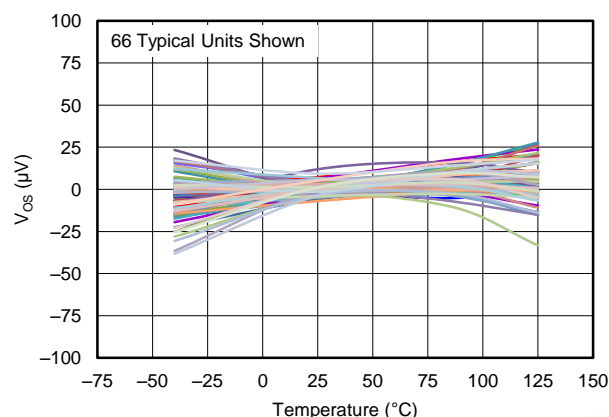


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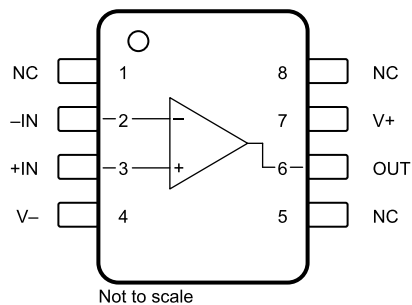
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4 Revision History

| DATE | REVISION | NOTES |
|---------------|----------|-----------------|
| December 2017 | * | Initial release |

5 Pin Configuration and Functions

**OPA192-Q1 DGK Package
8-Pin VSSOP
Top View**



NC – No internal connection.

Pin Functions: OPA192-Q1

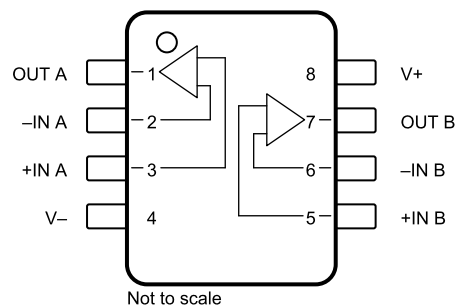
| PIN | | I/O | DESCRIPTION |
|------|--------------------------|-----|---|
| NAME | OPA192-Q1 DGK (VSSOP) | | |
| +IN | 3 | I | Noninverting input |
| -IN | 2 | I | Inverting input |
| NC | 1, 5, 8 | — | No internal connection (can be left floating) |
| OUT | 6 | O | Output |
| V+ | 7 | — | Positive (highest) power supply |
| V- | 4 | — | Negative (lowest) power supply |

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**OPA2192-Q1 DGK Package
8-Pin VSSOP
Top View**



Pin Functions: OPA2192-Q1

| PIN | | I/O | DESCRIPTION |
|-------|---------------------------|-----|---------------------------------|
| NAME | OPA2192-Q1 DGK (VSSOP) | | |
| +IN A | 3 | I | Noninverting input, channel A |
| +IN B | 5 | I | Noninverting input, channel B |
| +IN C | — | I | Noninverting input, channel C |
| +IN D | — | I | Noninverting input, channel D |
| –IN A | 2 | I | Inverting input, channel A |
| –IN B | 6 | I | Inverting input, channel B |
| –IN C | — | I | Inverting input, channel C |
| –IN D | — | I | Inverting input, channel D |
| OUT A | 1 | O | Output, channel A |
| OUT B | 7 | O | Output, channel B |
| OUT C | — | O | Output, channel C |
| OUT D | — | O | Output, channel D |
| V+ | 8 | — | Positive (highest) power supply |
| V– | 4 | — | Negative (lowest) power supply |

6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|-------------------------------------|---------------------------|--------------|---------------------------------|--------------|------|
| Supply voltage, $V_S = (V+) - (V-)$ | | | ± 20 (40, single-supply) | | V |
| Signal input pins | Voltage | Common-mode | $(V-) - 0.5$ | $(V+) + 0.5$ | V |
| | | Differential | $(V+) - (V-) + 0.2$ | | |
| | Current | ± 10 | | | mA |
| Output short circuit ⁽²⁾ | | | Continuous | | |
| Latch-up per JESD78D | | | Class 1 | | |
| Temperature | Operating range | | -55 | 150 | °C |
| | Junction | | | 150 | |
| | Storage, T_{stg} | | -65 | 150 | |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| OPA192-Q1 | | | | |
| V _(ESD) | Electrostatic discharge | Human body model (HBM), per AEC Q100-002 ⁽¹⁾ | ±4000 | V |
| | | Charged device model (CDM), per AEC Q100-011 | ±500 | |
| OPA2192-Q1 | | | | |
| V _(ESD) | Electrostatic discharge | Human body model (HBM), per AEC Q100-002 ⁽¹⁾ | ±4000 | V |
| | | Charged device model (CDM), per AEC Q100-011 | ±500 | |

(1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | MIN | NOM | MAX | UNIT |
|-------------------------------------|--------------------|-----|-----------------|------|
| Supply voltage, $V_S = (V+) - (V-)$ | 4.5 (± 2.25) | | 36 (± 18) | V |
| Specified temperature | -40 | | +125 | °C |

6.4 Thermal Information: OPA192-Q1

| THERMAL METRIC ⁽¹⁾ | | OPA192-Q1 | UNIT |
|-------------------------------|--|-------------|------|
| | | DGK (VSSOP) | |
| | | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 180.4 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 67.9 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 102.1 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 10.4 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 100.3 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | N/A | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Thermal Information: OPA2192-Q1

| THERMAL METRIC ⁽¹⁾ | | OPA2192-Q1 | UNIT |
|-------------------------------|--|-------------|------|
| | | DGK (VSSOP) | |
| | | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 158 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 48.6 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 78.7 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 3.9 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 77.3 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | N/A | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.6 Electrical Characteristics: $V_S = \pm 4\text{ V}$ to $\pm 18\text{ V}$ ($V_S = 8\text{ V}$ to 36 V)

at $T_A = 25^\circ\text{C}$, $V_{CM} = V_{OUT} = V_S / 2$, and $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|----------------------|------------------------------|---|---------------------------------|---|------------|------------|--------------------------|
| OFFSET VOLTAGE | | | | | | | |
| V _{OS} | Input offset voltage | | | | ±5 | ±25 | μV |
| | | T _A = 0°C to 85°C | | | ±8 | ±50 | |
| | | T _A = −40°C to 125°C | | | ±10 | ±75 | |
| | | V _{CM} = (V+) − 1.5 V | | ±10 | ±40 | | |
| | | | T _A = 0°C to 85°C | | ±25 | ±150 | |
| | | T _A = −40°C to 125°C | | ±50 | ±250 | | |
| dV _{OS} /dT | Input offset voltage drift | T _A = 0°C to 85°C | | | ±0.1 | ±0.8 | μV/°C |
| | | T _A = −40°C to 125°C | | | ±0.2 | ±1.0 | |
| PSRR | Power-supply rejection ratio | T _A = −40°C to 125°C | | | ±0.3 | ±1.0 | μV/V |
| INPUT BIAS CURRENT | | | | | | | |
| I _B | Input bias current | | | | ±5 | ±20 | pA |
| | | T _A = −40°C to 125°C | | | | ±5 | nA |
| I _{OS} | Input offset current | | | | ±2 | ±20 | pA |
| | | T _A = −40°C to 125°C | | | | ±2 | nA |
| NOISE | | | | | | | |
| E _n | Input voltage noise | (V−) − 0.1 V < V _{CM} < (V+) − 3 V | f = 0.1 Hz to 10 Hz | | 1.30 | | μV _{PP} |
| | | (V+) − 1.5 V < V _{CM} < (V+) + 0.1 V | f = 0.1 Hz to 10 Hz | | 4 | | |
| e _n | Input voltage noise density | (V−) − 0.1 V < V _{CM} < (V+) − 3 V | f = 100 Hz | | 10.5 | | nV/√Hz |
| | | | f = 1 kHz | | 5.5 | | |
| | | (V+) − 1.5 V < V _{CM} < (V+) + 0.1 V | f = 100 Hz | | 32 | | |
| | | | f = 1 kHz | | 12.5 | | |
| NOISE (continued) | | | | | | | |
| i _n | Input current noise density | f = 1 kHz | | | 1.5 | | fA/√Hz |
| INPUT VOLTAGE | | | | | | | |
| V _{CM} | Common-mode voltage range | | | (V−) − 0.1 | | (V+) + 0.1 | V |
| CMRR | Common-mode rejection ratio | (V−) − 0.1 V < V _{CM} < (V+) − 3 V | | 120 | 140 | | dB |
| | | | T _A = −40°C to 125°C | | 114 | 126 | |
| | | (V+) − 1.5 V < V _{CM} < (V+) | | 100 | 120 | | |
| | | | T _A = −40°C to 125°C | | 86 | 100 | |
| | | (V+) − 3 V < V _{CM} < (V+) − 1.5 V | | See Typical Characteristics | | | |
| INPUT IMPEDANCE | | | | | | | |
| Z _{ID} | Differential | | | | 100 1.6 | | MΩ pF |
| Z _{IC} | Common-mode | | | | 1 6.4 | | 10 ¹³ Ω pF |
| OPEN-LOOP GAIN | | | | | | | |
| A _{OL} | Open-loop voltage gain | (V−) + 0.6 V < V _O < (V+) − 0.6 V, R _{LOAD} = 2 kΩ | | 120 | 134 | | dB |
| | | | T _A = −40°C to 125°C | | 114 | 126 | |
| | | (V−) + 0.3 V < V _O < (V+) − 0.3 V, R _{LOAD} = 10 kΩ | | 126 | 140 | | |
| | | | T _A = −40°C to 125°C | | 120 | 134 | |

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Electrical Characteristics: $V_S = \pm 4\text{ V}$ to $\pm 18\text{ V}$ ($V_S = 8\text{ V}$ to 36 V) (continued)

at $T_A = 25^\circ\text{C}$, $V_{CM} = V_{OUT} = V_S / 2$, and $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|--------------------|-----------------------------------|--|--|---|-----|-----|------|
| FREQUENCY RESPONSE | | | | | | | |
| GBW | Unity gain bandwidth | | | 10 | | | MHz |
| SR | Slew rate | G = 1, 10-V step | | 20 | | | V/μs |
| t _s | Settling time | To 0.01% | V _S = ±18 V, G = 1, 10-V step | 1.4 | | μs | |
| | | | V _S = ±18 V, G = 1, 5-V step | 0.9 | | | |
| | | To 0.001% | V _S = ±18 V, G = 1, 10-V step | 2.1 | | | |
| | | | V _S = ±18 V, G = 1, 5-V step | 1.8 | | | |
| t _{OR} | Overload recovery time | V _{IN} × G = V _S | | | 200 | | ns |
| THD+N | Total harmonic distortion + noise | G = 1, f = 1 kHz, V _O = 3.5 V _{RMS} | | 0.00008% | | | |
| | Crosstalk | OPA2192-Q1 at dc | | 150 | | dB | |
| | | OPA2192-Q1 at f = 100 kHz | | 130 | | | |
| OUTPUT | | | | | | | |
| V _O | Voltage output swing from rail | Positive rail | No load | 5 | | 15 | mV |
| | | | R _{LOAD} = 10 kΩ | 95 | | 110 | |
| | | | R _{LOAD} = 2 kΩ | 430 | | 500 | |
| | | Negative rail | No load | 5 | | 15 | |
| | | | R _{LOAD} = 10 kΩ | 95 | | 110 | |
| | | | R _{LOAD} = 2 kΩ | 430 | | 500 | |
| I _{SC} | Short-circuit current | | | ±65 | | | mA |
| C _{LOAD} | Capacitive load drive | | | See Typical Characteristics | | | |
| Z _O | Open-loop output impedance | f = 1 MHz, I _O = 0 A; see Figure 29 | | 375 | | | Ω |
| POWER SUPPLY | | | | | | | |
| I _Q | Quiescent current per amplifier | I _O = 0 A | | 1 | | 1.2 | mA |
| | | T _A = −40°C to 125°C, I _O = 0 A | | | | 1.5 | |
| TEMPERATURE | | | | | | | |
| | Thermal protection ⁽¹⁾ | | | 140 | | | °C |

(1) For a detailed description of thermal protection, see [Thermal Protection](#).

6.7 Electrical Characteristics: $V_S = \pm 2.25\text{ V}$ to $\pm 4\text{ V}$ ($V_S = 4.5\text{ V}$ to 8 V)

at $T_A = 25^\circ\text{C}$, $V_{CM} = V_{OUT} = V_S / 2$, and $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|---------------------------------|------------------------------|--|---------------------------------|--------------------------------------|------------|--------------------------|------|
| OFFSET VOLTAGE | | | | | | | |
| V _{OS} | Input offset voltage | V _{CM} = (V+) – 3 V | | ±5 | ±25 | μV | |
| | | | T _A = 0°C to 85°C | ±8 | ±50 | | |
| | | | T _A = –40°C to 125°C | ±10 | ±75 | | |
| | | (V+) – 3.5 V < V _{CM} < (V+) – 1.5 V | | See <i>Common-Mode Voltage Range</i> | | | |
| | | V _{CM} = (V+) – 1.5 V | | ±10 | ±40 | μV | |
| T _A = 0°C to 85°C | ±25 | | ±150 | | | | |
| T _A = –40°C to 125°C | ±50 | | ±250 | | | | |
| dV _{OS} /dT | Input offset voltage drift | V _{CM} = (V+) – 3 V | T _A = 0°C to 85°C | ±0.1 | ±0.8 | μV/°C | |
| | | | T _A = –40°C to 125°C | ±0.2 | ±1.1 | | |
| | | V _{CM} = (V+) – 1.5 V, T _A = –40°C to 125°C | | ±0.5 | ±3 | | |
| PSRR | Power-supply rejection ratio | T _A = –40°C to 125°C, V _{CM} = V _S / 2 – 0.75 V | | ±1 | | μV/V | |
| INPUT BIAS CURRENT | | | | | | | |
| I _B | Input bias current | | | ±5 | ±20 | pA | |
| | | T _A = –40°C to 125°C | | | ±5 | nA | |
| I _{OS} | Input offset current | | | ±2 | ±20 | pA | |
| | | T _A = –40°C to 125°C | | | ±2 | nA | |
| NOISE | | | | | | | |
| E _n | Input voltage noise | (V–) – 0.1 V < V _{CM} < (V+) – 3 V, f = 0.1 Hz to 10 Hz | | 1.30 | | μV _{PP} | |
| | | (V+) – 1.5 V < V _{CM} < (V+) + 0.1 V, f = 0.1 Hz to 10 Hz | | 4 | | | |
| e _n | Input voltage noise density | (V–) – 0.1 V < V _{CM} < (V+) – 3 V | f = 100 Hz | 10.5 | | nV/√Hz | |
| | | | f = 1 kHz | 5.5 | | | |
| | | (V+) – 1.5 V < V _{CM} < (V+) + 0.1 V | f = 100 Hz | 32 | | | |
| | | | f = 1 kHz | 12.5 | | | |
| i _n | Input current noise density | f = 1 kHz | | 1.5 | | fA/√Hz | |
| INPUT VOLTAGE | | | | | | | |
| V _{CM} | Common-mode voltage range | | | (V–) – 0.1 | (V+) + 0.1 | V | |
| CMRR | Common-mode rejection ratio | (V–) – 0.1 V < V _{CM} < (V+) – 3 V | | 94 | 110 | dB | |
| | | | T _A = –40°C to 125°C | 90 | 104 | | |
| | | (V+) – 1.5 V < V _{CM} < (V+) | | 100 | 120 | | |
| | | | T _A = –40°C to 125°C | 84 | 100 | | |
| | | (V+) – 3 V < V _{CM} < (V+) – 1.5 V | | See <i>Typical Characteristics</i> | | | |
| INPUT IMPEDANCE | | | | | | | |
| Z _{ID} | Differential | | | 100 1.6 | | MΩ pF | |
| Z _{IC} | Common-mode | | | 1 6.4 | | 10 ¹³ Ω pF | |
| OPEN-LOOP GAIN | | | | | | | |
| A _{OL} | Open-loop voltage gain | (V–) + 0.6 V < V _O < (V+) – 0.6 V, R _{LOAD} = 2 kΩ | | 110 | 120 | dB | |
| | | | T _A = –40°C to 125°C | 100 | 114 | | |
| | | (V–) + 0.3 V < V _O < (V+) – 0.3 V, R _{LOAD} = 10 kΩ | | 110 | 126 | | |
| | | | T _A = –40°C to 125°C | 110 | 120 | | |

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Electrical Characteristics: $V_S = \pm 2.25\text{ V}$ to $\pm 4\text{ V}$ ($V_S = 4.5\text{ V}$ to 8 V) (continued)

at $T_A = 25^\circ\text{C}$, $V_{CM} = V_{OUT} = V_S / 2$, and $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------------------------------|---------------------------------|--|--|------------------------------------|-----|------|------|
| FREQUENCY RESPONSE | | | | | | | |
| GBW | Unity gain bandwidth | | | 10 | | MHz | |
| SR | Slew rate | G = 1, 10-V step | | 20 | | V/μs | |
| t _s | Settling time | To 0.01% | V _S = ±3 V, G = 1, 5-V step | 1 | | μs | |
| t _{OR} | Overload recovery time | V _{IN} × G = V _S | | 200 | | ns | |
| Crosstalk | | OPA2192-Q1 at dc | | 150 | | dB | |
| | | OPA2192-Q1 f = 100 kHz | | 130 | | | |
| OUTPUT | | | | | | | |
| V _O | Voltage output swing from rail | Positive rail | No load | 5 | | 15 | mV |
| | | | R _{LOAD} = 10 kΩ | 95 | | 110 | |
| | | | R _{LOAD} = 2 kΩ | 430 | | 500 | |
| | | Negative rail | No load | 5 | | 15 | |
| | | | R _{LOAD} = 10 kΩ | 95 | | 110 | |
| | | | R _{LOAD} = 2 kΩ | 430 | | 500 | |
| I _{SC} | Short-circuit current | | | ±65 | | mA | |
| C _{LOAD} | Capacitive load drive | | | See <i>Typical Characteristics</i> | | | |
| Z _O | Open-loop output impedance | f = 1 MHz, I _O = 0 A; see Figure 29 | | 375 | | Ω | |
| POWER SUPPLY | | | | | | | |
| I _Q | Quiescent current per amplifier | I _O = 0 A | | 1 | | 1.2 | mA |
| | | | T _A = −40°C to 125°C | 1.5 | | | |
| TEMPERATURE | | | | | | | |
| Thermal protection ⁽¹⁾ | | | | 140 | | °C | |

(1) For a detailed description of thermal protection, see [Thermal Protection](#).

6.8 Typical Characteristics

Table 1. Table of Graphs

| DESCRIPTION | FIGURE |
|--|--|
| Offset Voltage Production Distribution | Figure 1 to Figure 6 |
| Offset Voltage Drift Distribution | Figure 7 to Figure 8 |
| Offset Voltage vs Temperature | Figure 9 |
| Offset Voltage vs Common-Mode Voltage | Figure 10 to Figure 12 |
| Offset Voltage vs Power Supply | Figure 13 |
| Open-Loop Gain and Phase vs Frequency | Figure 14 |
| Closed-Loop Gain and Phase vs Frequency | Figure 15 |
| Input Bias Current vs Common-Mode Voltage | Figure 16 |
| Input Bias Current vs Temperature | Figure 17 |
| Output Voltage Swing vs Output Current (maximum supply) | Figure 18 |
| CMRR and PSRR vs Frequency | Figure 19 |
| CMRR vs Temperature | Figure 20 |
| PSRR vs Temperature | Figure 21 |
| 0.1-Hz to 10-Hz Noise | Figure 22 |
| Input Voltage Noise Spectral Density vs Frequency | Figure 23 |
| THD+N Ratio vs Frequency | Figure 24 |
| THD+N vs Output Amplitude | Figure 25 |
| Quiescent Current vs Supply Voltage | Figure 26 |
| Quiescent Current vs Temperature | Figure 27 |
| Open Loop Gain vs Temperature | Figure 28 |
| Open Loop Output Impedance vs Frequency | Figure 29 |
| Small Signal Overshoot vs Capacitive Load (100-mV Output Step) | Figure 30, Figure 31 |
| No Phase Reversal | Figure 32 |
| Positive Overload Recovery | Figure 33 |
| Negative Overload Recovery | Figure 34 |
| Small-Signal Step Response (100 mV) | Figure 35, Figure 36 |
| Large-Signal Step Response | Figure 37 |
| Settling Time | Figure 38 to Figure 41 |
| Short-Circuit Current vs Temperature | Figure 42 |
| Maximum Output Voltage vs Frequency | Figure 43 |
| Propagation Delay Rising Edge | Figure 44 |
| Propagation Delay Falling Edge | Figure 45 |
| Crosstalk vs Frequency | Figure 46 |

6.9 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $V_S = \pm 18\text{ V}$, $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$, and $C_L = 100\text{ pF}$, (unless otherwise noted)

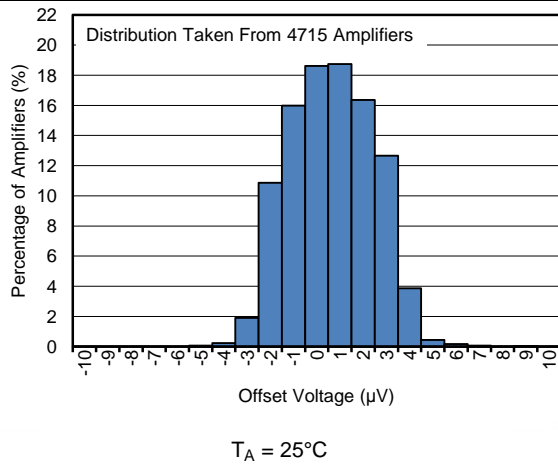


Figure 1. Offset Voltage Production Distribution at 25°C

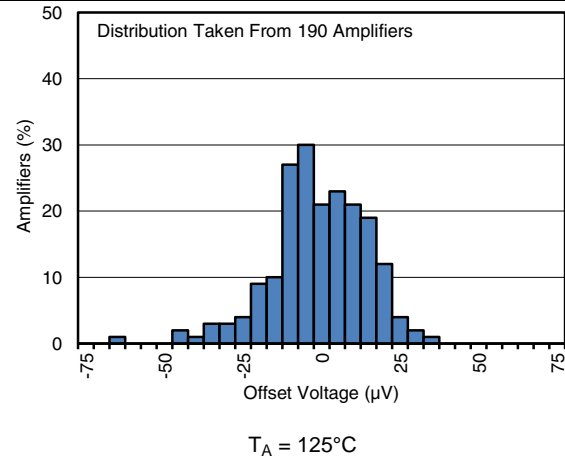


Figure 2. Offset Voltage Production Distribution at 125°C

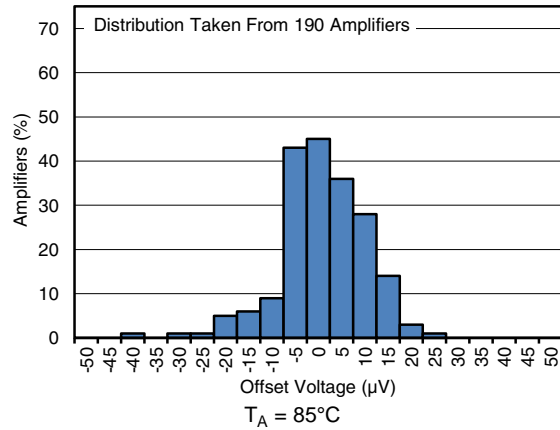


Figure 3. Offset Voltage Production Distribution at 85°C

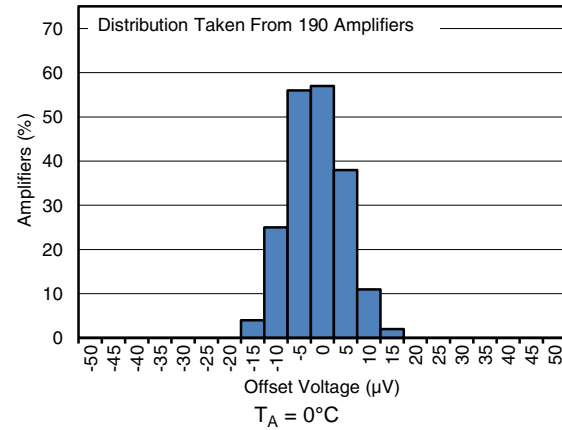


Figure 4. Offset Voltage Production Distribution at 0°C

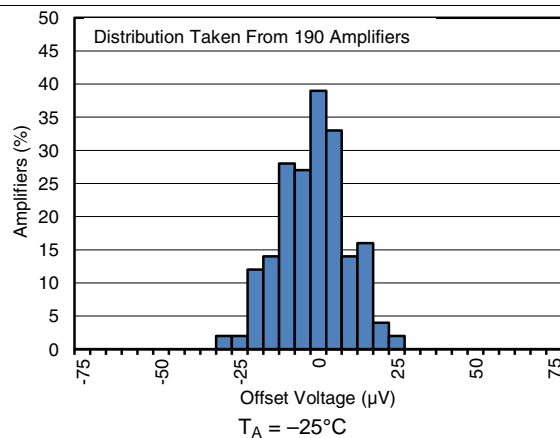


Figure 5. Offset Voltage Production Distribution at -25°C

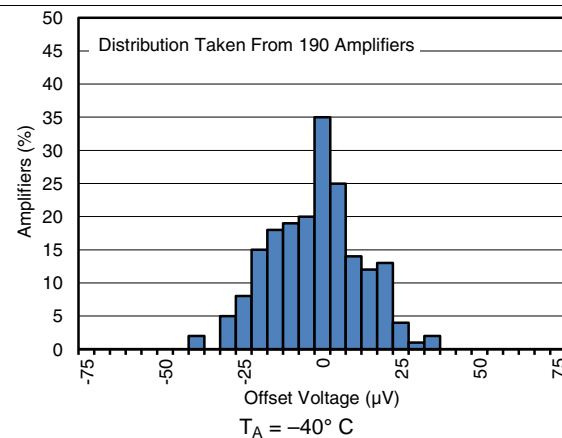


Figure 6. Offset Voltage Production Distribution at -40°C

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 18\text{ V}$, $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$, and $C_L = 100\text{ pF}$, (unless otherwise noted)

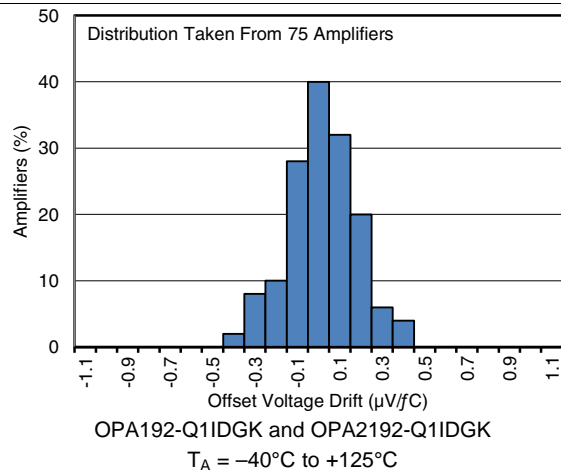


Figure 7. Offset Voltage Drift Distribution

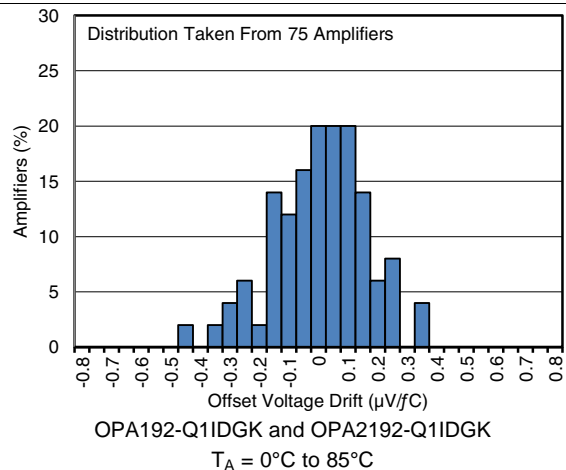


Figure 8. Offset Voltage Drift Distribution

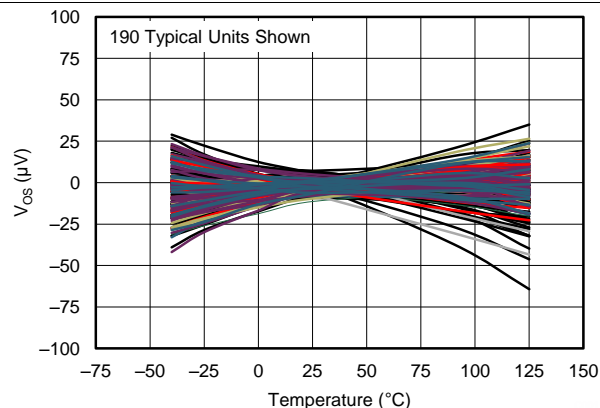


Figure 9. Offset Voltage vs Temperature

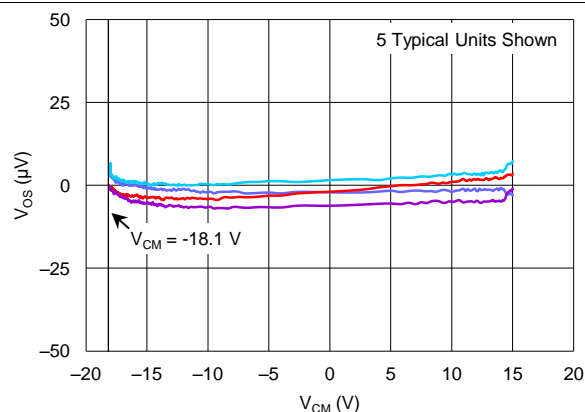


Figure 10. Offset Voltage vs Common-Mode Voltage

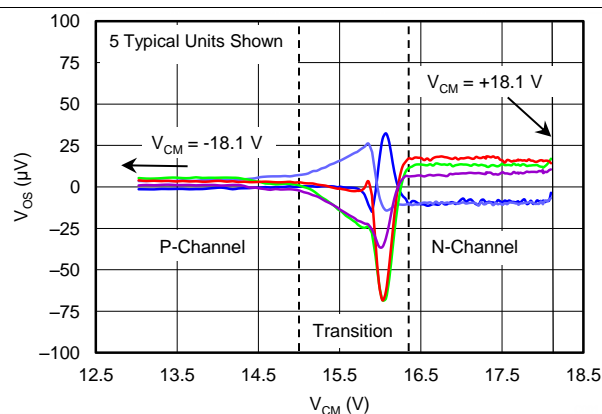


Figure 11. Offset Voltage vs Common-Mode Voltage

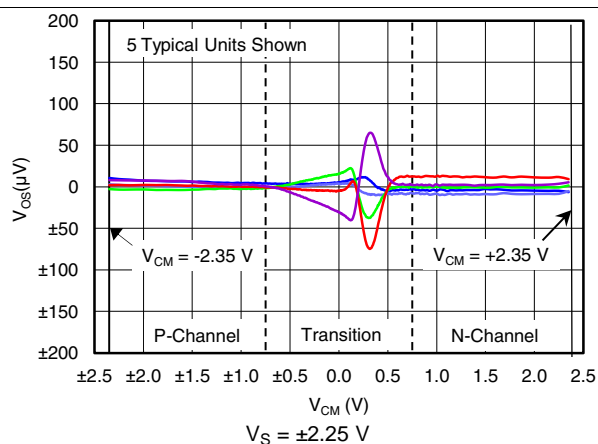


Figure 12. Offset Voltage vs Common-Mode Voltage

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 18\text{ V}$, $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$, and $C_L = 100\text{ pF}$, (unless otherwise noted)

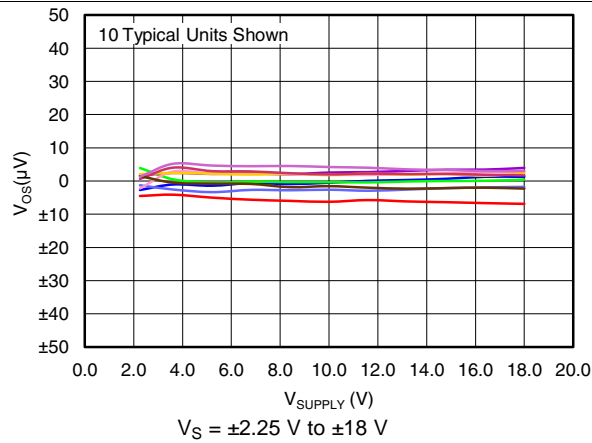


Figure 13. Offset Voltage vs Power Supply

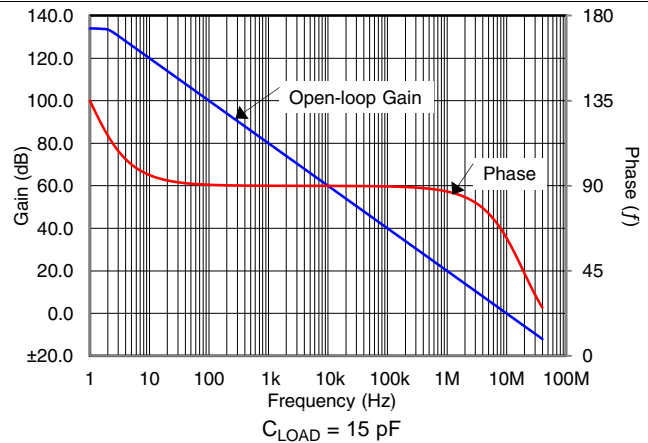


Figure 14. Open-Loop Gain and Phase vs Frequency

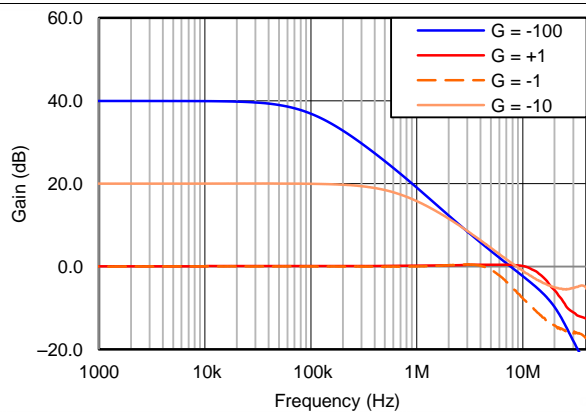


Figure 15. Closed-Loop Gain and Phase vs Frequency

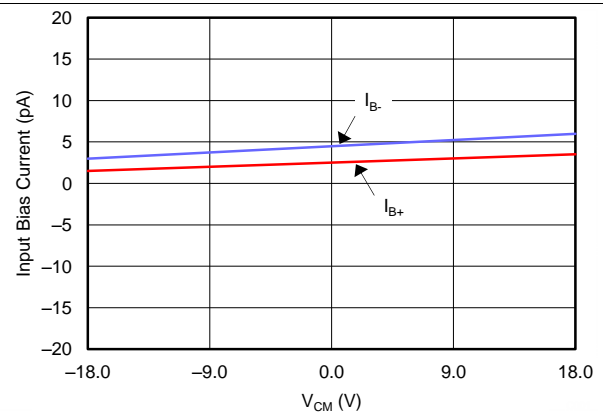


Figure 16. Input Bias Current vs Common-Mode Voltage

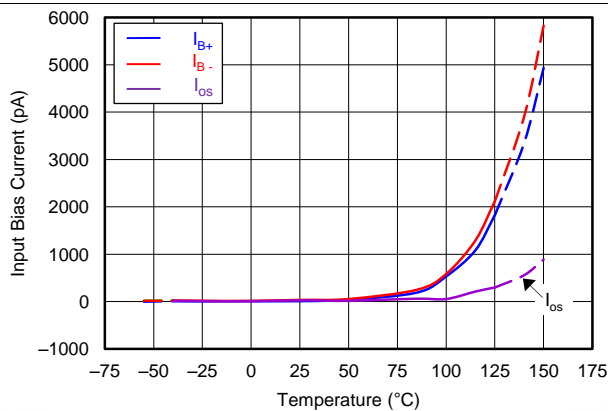


Figure 17. Input Bias Current vs Temperature

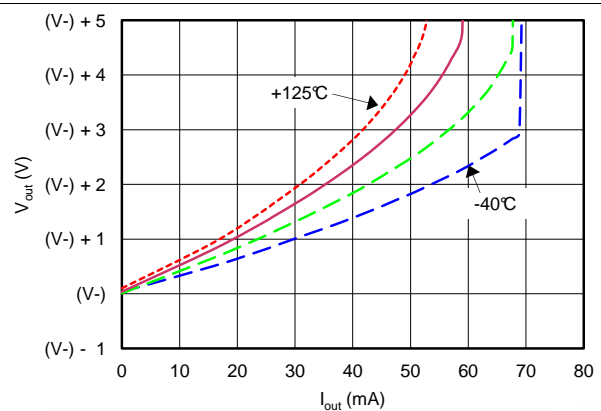


Figure 18. Output Voltage Swing vs Output Current (Maximum Supply)

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 18\text{ V}$, $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$, and $C_L = 100\text{ pF}$, (unless otherwise noted)

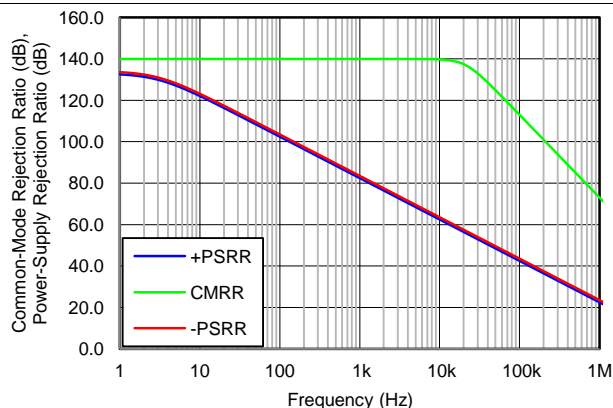


Figure 19. CMRR and PSRR vs Frequency

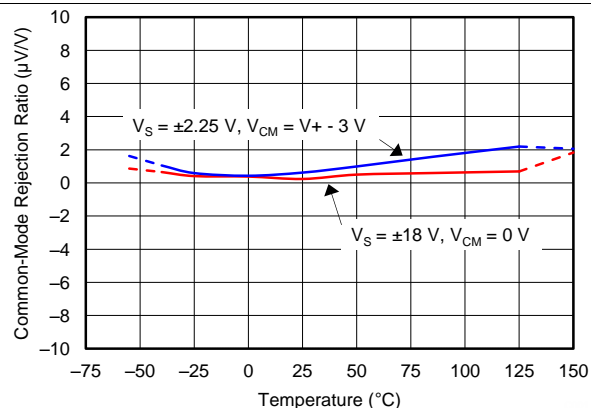


Figure 20. CMRR vs Temperature

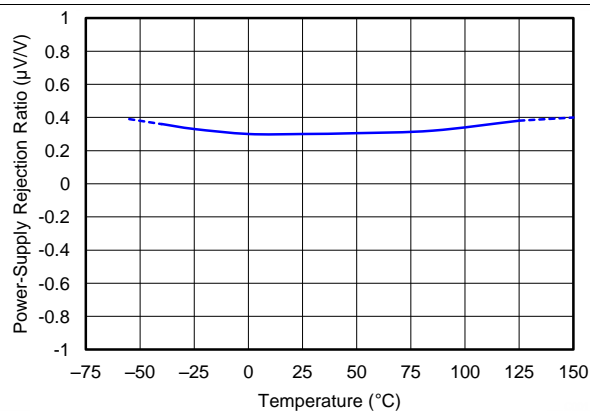


Figure 21. PSRR vs Temperature

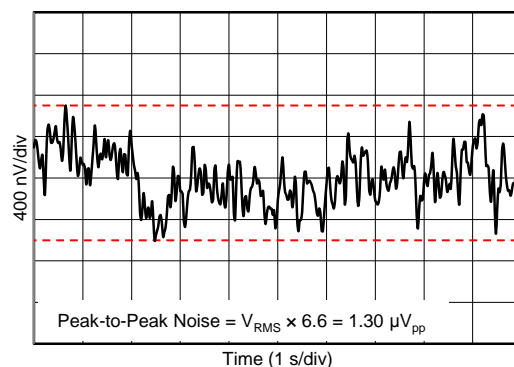


Figure 22. 0.1-Hz to 10-Hz Noise

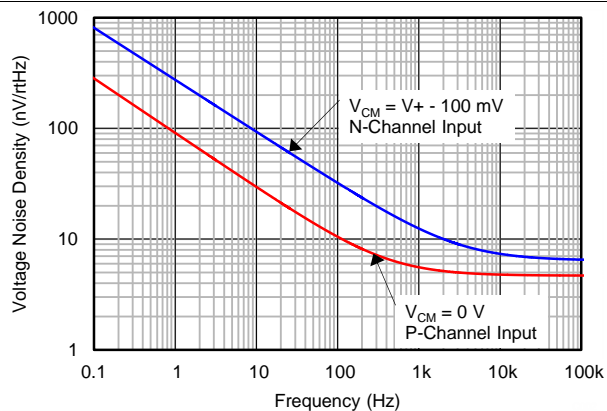


Figure 23. Input Voltage Noise Spectral Density vs Frequency

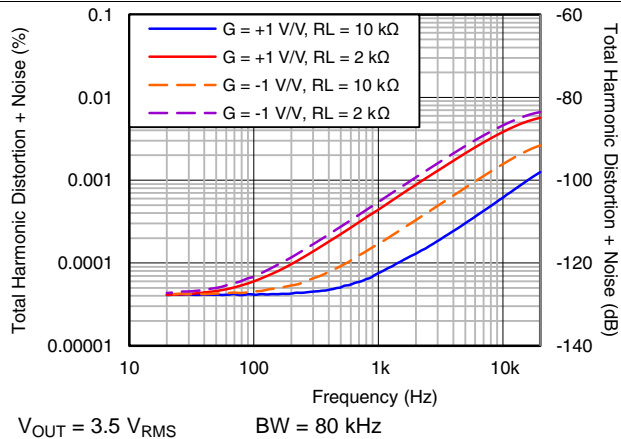


Figure 24. THD+N Ratio vs Frequency

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 18\text{ V}$, $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$, and $C_L = 100\text{ pF}$, (unless otherwise noted)

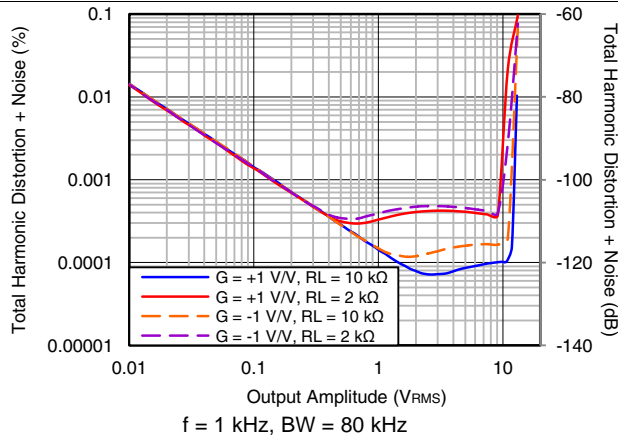


Figure 25. THD+N vs Output Amplitude

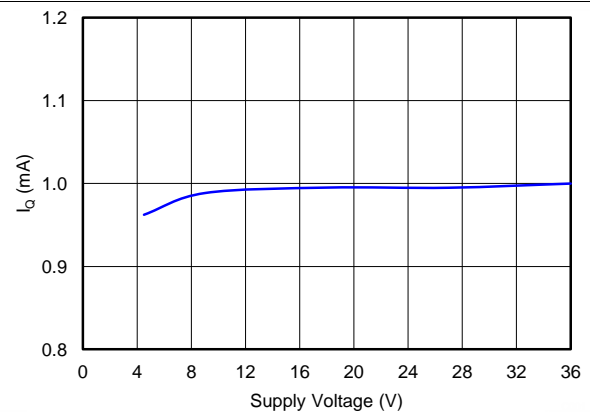


Figure 26. Quiescent Current vs Supply Voltage

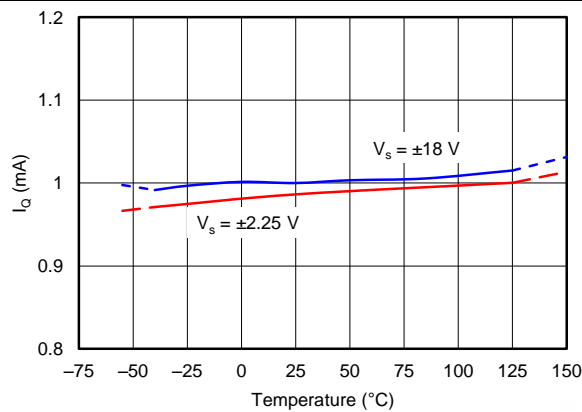


Figure 27. Quiescent Current vs Temperature

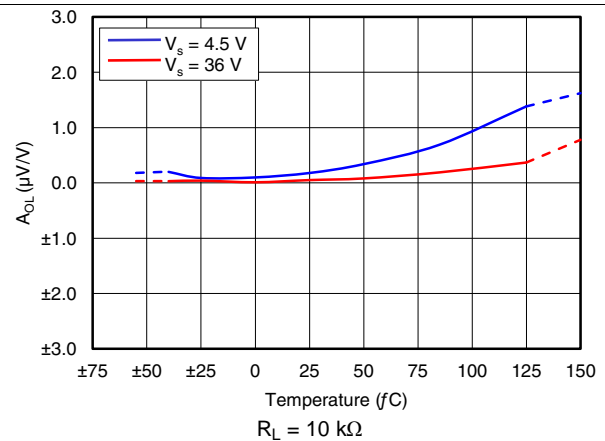


Figure 28. Open-Loop Gain vs Temperature

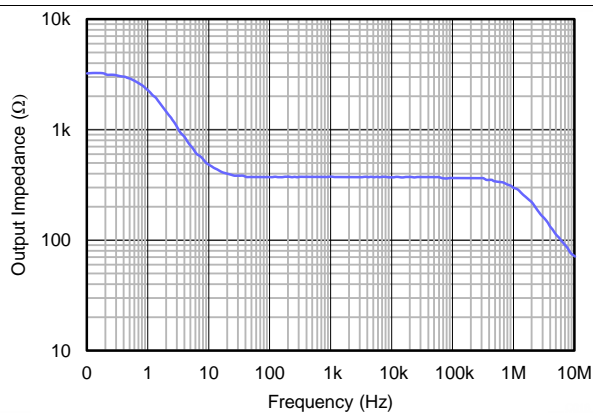


Figure 29. Open-Loop Output Impedance vs Frequency

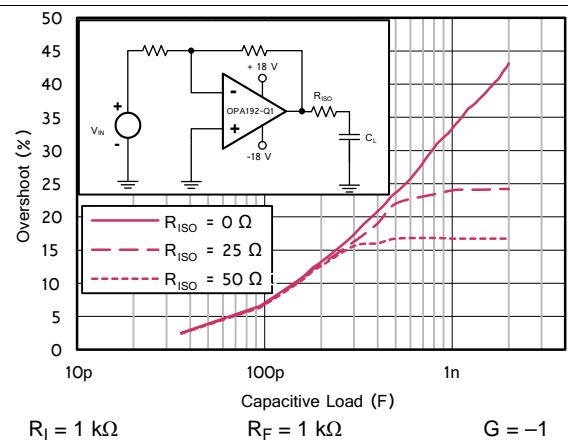


Figure 30. Small-Signal Overshoot vs Capacitive Load (100-mV Output Step)

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 18\text{ V}$, $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$, and $C_L = 100\text{ pF}$, (unless otherwise noted)

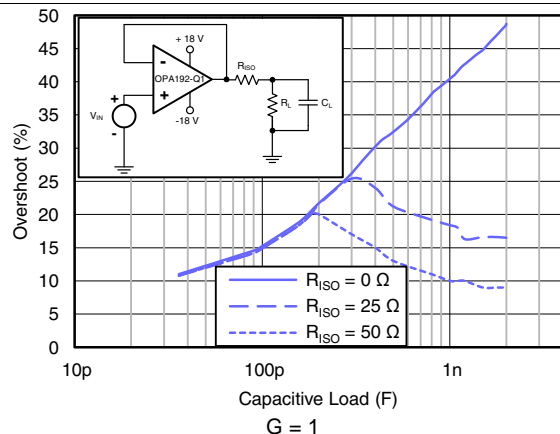


Figure 31. Small-Signal Overshoot vs Capacitive Load (100-mV Output Step)

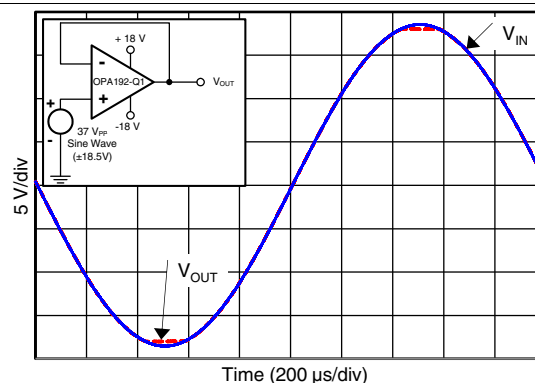


Figure 32. No Phase Reversal

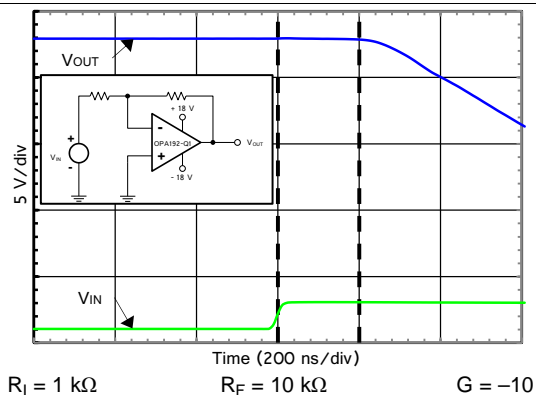


Figure 33. Positive Overload Recovery

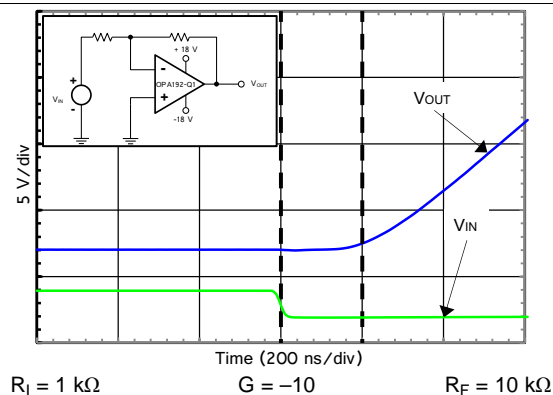


Figure 34. Negative Overload Recovery

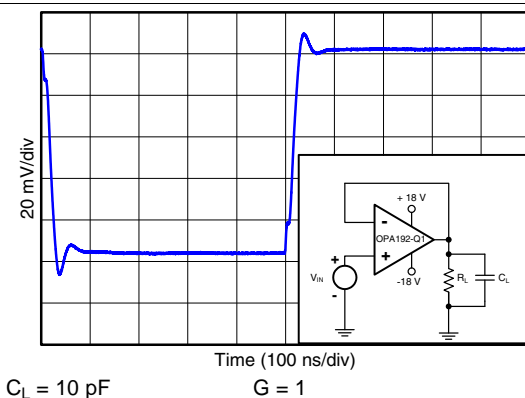


Figure 35. Small-Signal Step Response (100 mV)

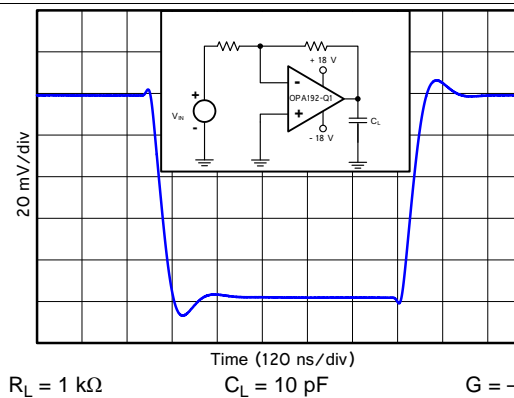
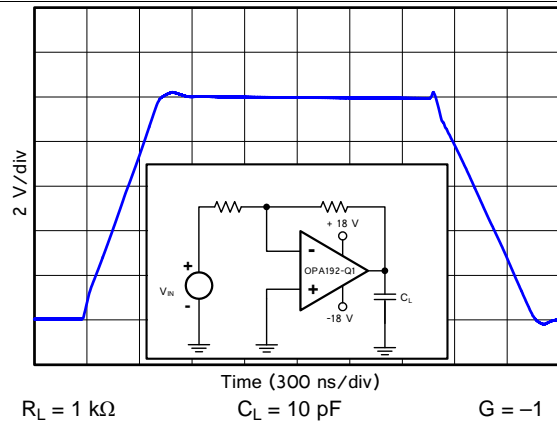
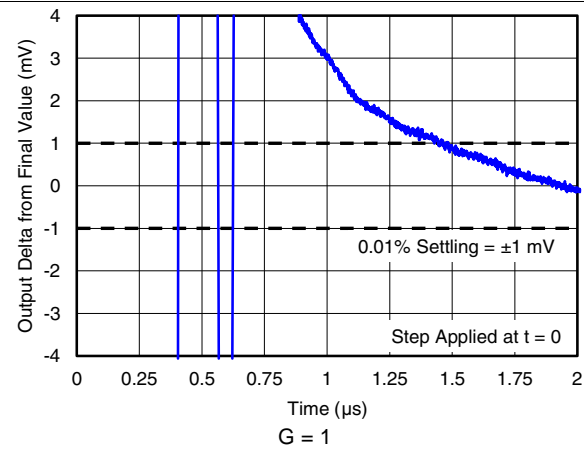
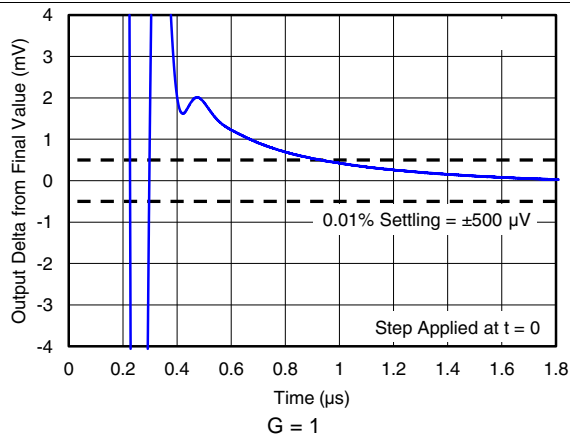
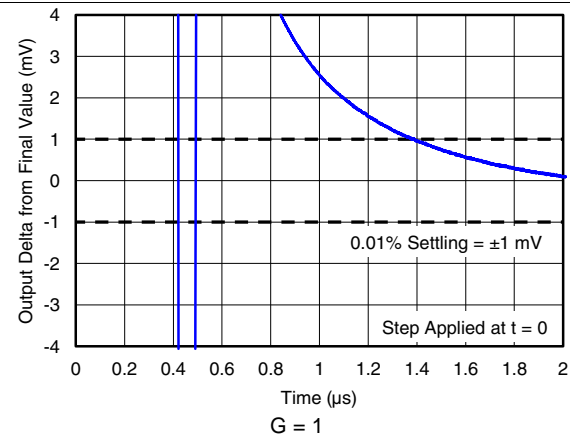
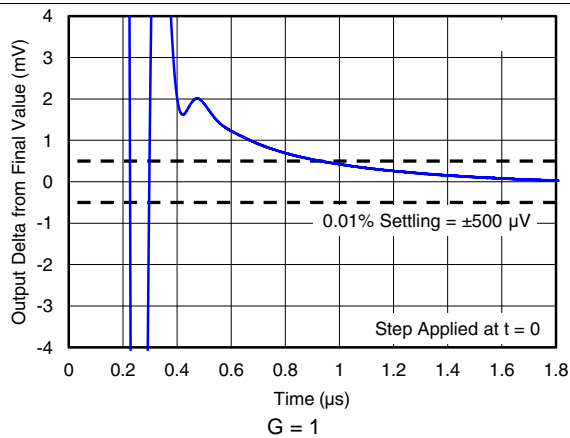
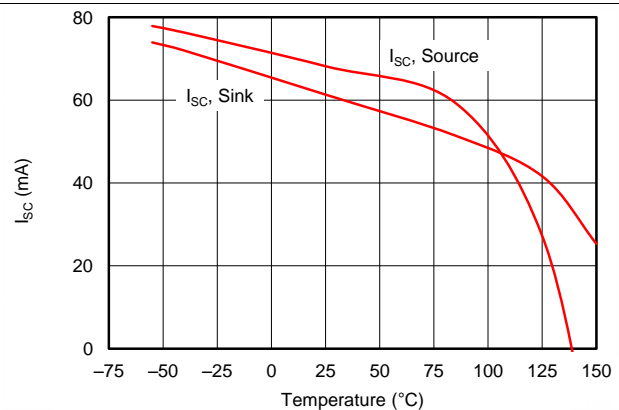


Figure 36. Small-Signal Step Response (100 mV)

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 18\text{ V}$, $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$, and $C_L = 100\text{ pF}$, (unless otherwise noted)


Figure 37. Large-Signal Step Response

Figure 38. Settling Time (10-V Positive Step)

Figure 39. Settling Time (5-V Positive Step)

Figure 40. Settling Time (10-V Negative Step)

Figure 41. Settling Time (5-V Negative Step)

Figure 42. Short-Circuit Current vs Temperature

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 18\text{ V}$, $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$, and $C_L = 100\text{ pF}$, (unless otherwise noted)

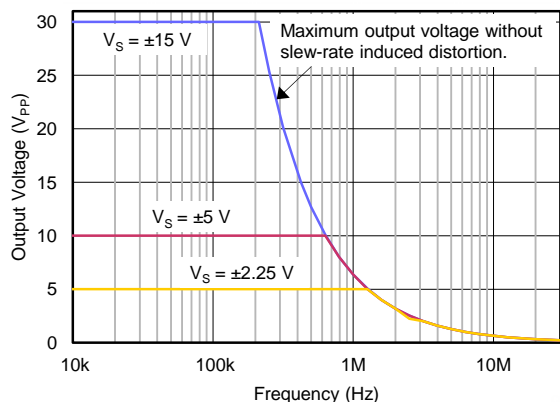


Figure 43. Maximum Output Voltage vs Frequency

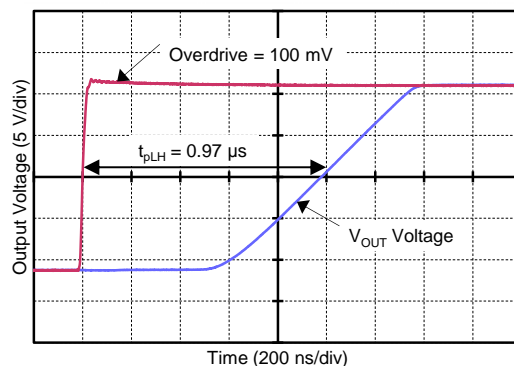


Figure 44. Propagation Delay Rising Edge

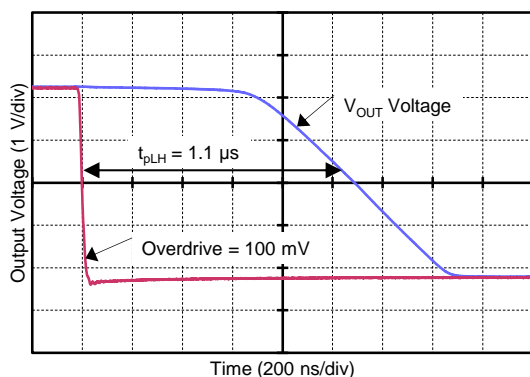


Figure 45. Propagation Delay Falling Edge

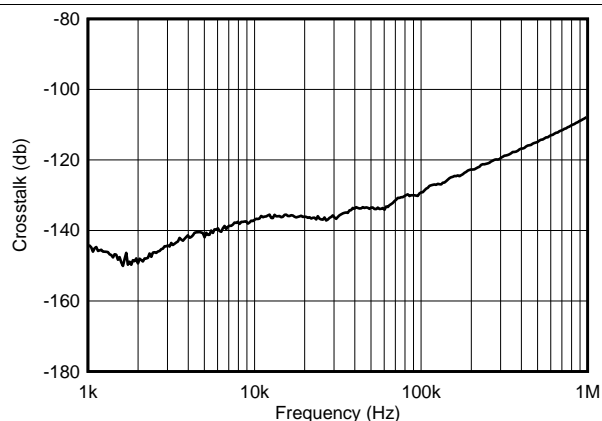


Figure 46. Crosstalk vs Frequency

7 Parameter Measurement Information

7.1 Input Offset Voltage Drift

The OPAx192-Q1 family of operational amplifiers is manufactured using TI's e-trim technology. Each amplifier input offset voltage and input offset voltage drift is trimmed in production, thereby minimizing errors associated with input offset voltage and input offset voltage drift. The e-trim technology is a TI proprietary method of trimming internal device parameters during either wafer probing or final testing. When trimming input offset voltage drift the systematic or linear drift error on each device is trimmed to zero. This results in the remaining errors associated with input offset drift are minimal and are the result from only nonlinear error sources. Figure 47 illustrates this concept.

Input Offset Voltage Drift (continued)

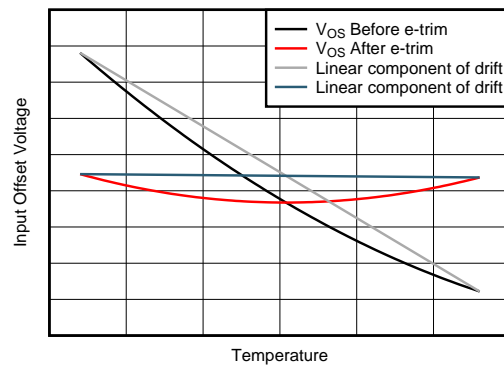


Figure 47. Input Offset Before and After Drift Trim

Figure 48 shows six typical units.

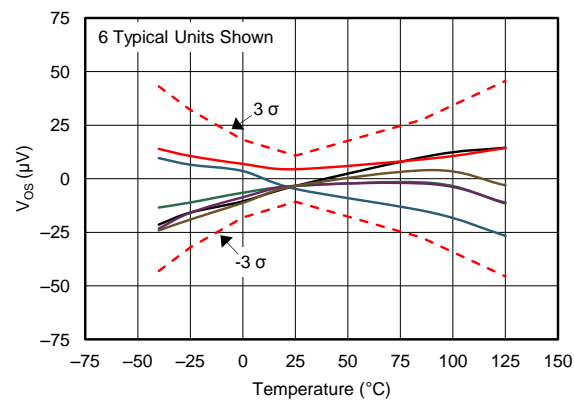


Figure 48. Input Offset Voltage Drift vs Temperature for Six Typical Units

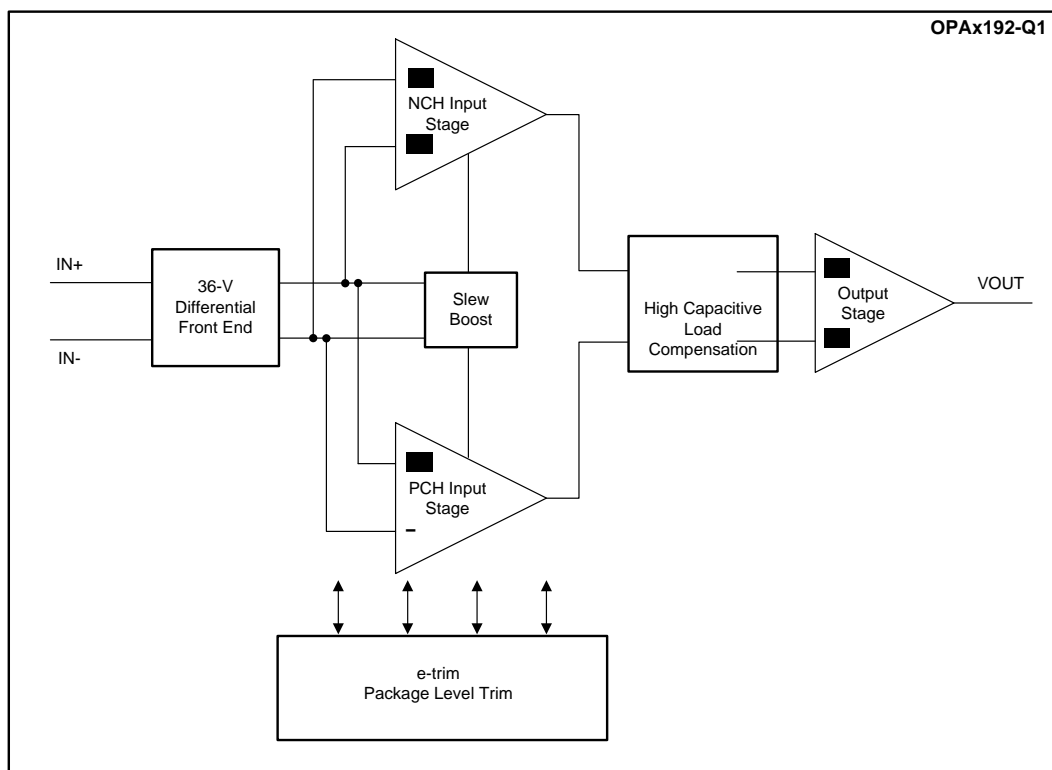
8 Detailed Description

8.1 Overview

The OPAx192-Q1 family of operational amplifiers use *e-trim*, a method of package-level trim for offset and offset temperature drift implemented during the final steps of manufacturing after the plastic molding process. This method minimizes the influence of inherent input transistor mismatch, as well as errors induced during package molding. The trim communication occurs on the output pin of the standard pinout, and after the trim points are set, further communication to the trim structure is permanently disabled. The [Functional Block Diagram](#) shows the simplified diagram of the OPAx192-Q1 with e-trim.

Unlike previous e-trim op amps, the OPAx192-Q1 uses a patented two-temperature trim architecture to achieve a very low offset voltage of 25 μV (maximum) and low voltage offset drift of 0.5 $\mu\text{V}/^\circ\text{C}$ (maximum) over the full specified temperature range. This level of precision performance at wide supply voltages makes these amplifiers useful for high-impedance industrial sensors, filters, and high-voltage data acquisition.

8.2 Functional Block Diagram

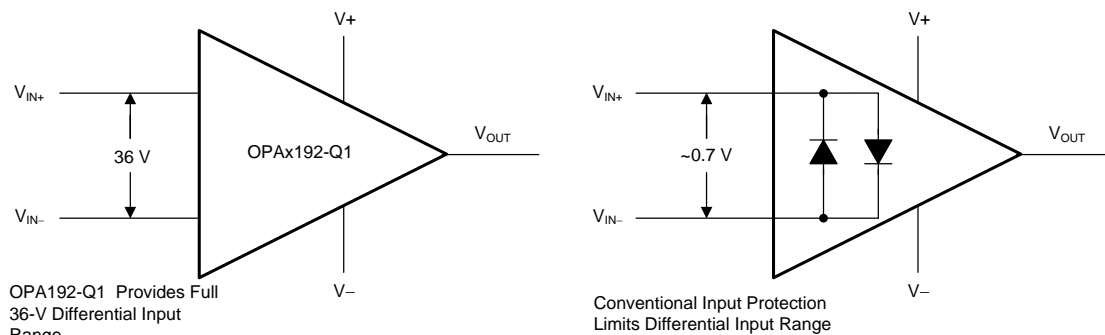


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8.3 Feature Description

8.3.1 Input Protection Circuitry

The OPAx192-Q1 uses a unique input architecture to eliminate the need for input protection diodes but still provides robust input protection under transient conditions. Conventional input diode protection schemes shown in Figure 49 can be activated by fast transient step responses and can introduce signal distortion and settling time delays because of alternate current paths, as shown in Figure 50. For low-gain circuits, these fast-ramping input signals forward-bias back-to-back diodes, causing an increase in input current, and resulting in extended settling time, as shown in Figure 51.



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Figure 49. OPAx192-Q1 Input Protection Does Not Limit Differential Input Capability

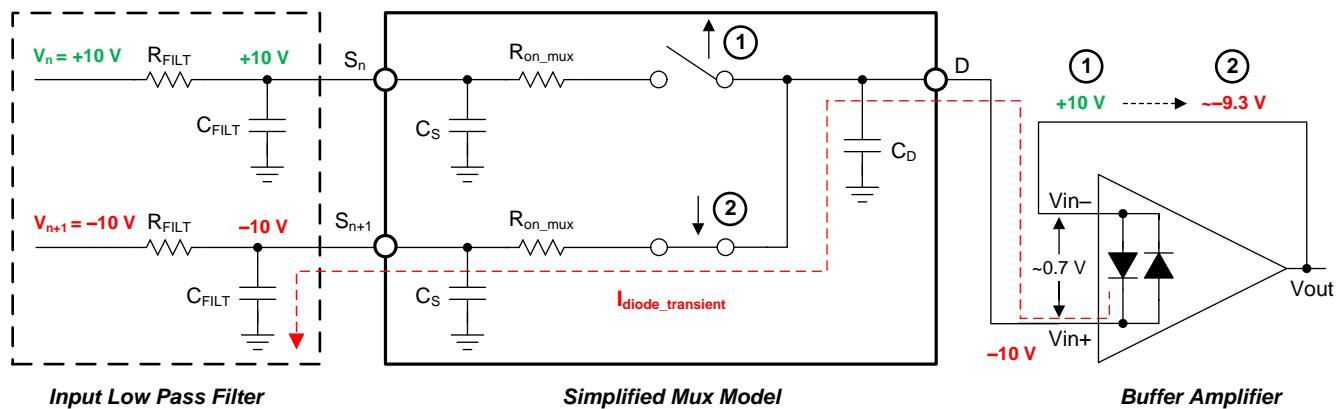


Figure 50. Back-to-Back Diodes Create Settling Issues

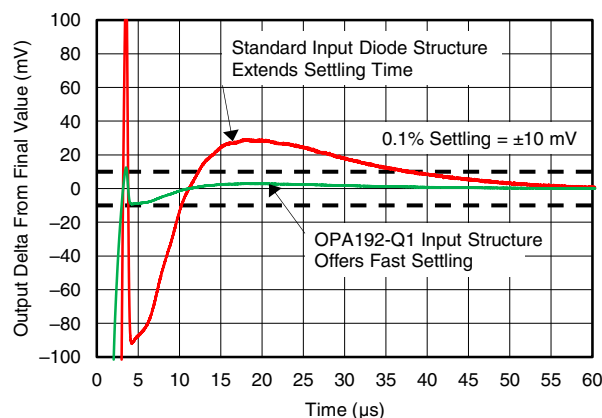


Figure 51. OPAx192-Q1 Protection Circuit Maintains Fast-Settling Transient Response

Feature Description (continued)

The OPAx192-Q1 family of operational amplifiers provides a true high-impedance differential input capability for high-voltage applications. This patented input protection architecture does not introduce additional signal distortion or delayed settling time, making the device an optimal op amp for multichannel, high-switched, input applications. The OPAx192-Q1 can tolerate a maximum differential swing (voltage between inverting and noninverting pins of the op amp) of up to 36 V, making the device suitable for use as a comparator or in applications with fast-ramping input signals such as multiplexed data-acquisition systems; see [Figure 61](#).

8.3.2 EMI Rejection

The OPAx192-Q1 uses integrated electromagnetic interference (EMI) filtering to reduce the effects of EMI from sources such as wireless communications and densely-populated boards with a mix of analog signal chain and digital components. EMI immunity can be improved with circuit design techniques; the OPAx192-Q1 benefits from these design improvements. Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. [Figure 52](#) shows the results of this testing on the OPAx192-Q1. [Table 2](#) shows the EMIRR IN+ values for the OPAx192-Q1 at particular frequencies commonly encountered in real-world applications. Applications listed in [Table 2](#) may be centered on or operated near the particular frequency shown. Detailed information can also be found in the application report [EMI Rejection Ratio of Operational Amplifiers](#) available for download from [www.ti.com](#).

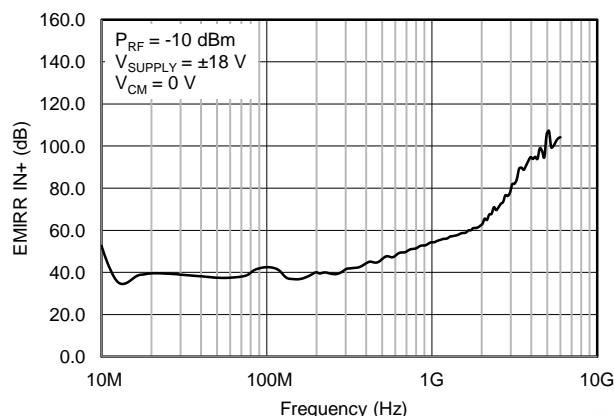


Figure 52. EMIRR Testing

Table 2. OPAx192-Q1 EMIRR IN+ For Frequencies of Interest

| FREQUENCY | APPLICATION OR ALLOCATION | EMIRR IN+ |
|-----------|--|-----------|
| 400 MHz | Mobile radio, mobile satellite, space operation, weather, radar, ultra-high frequency (UHF) applications | 44.1 dB |
| 900 MHz | Global system for mobile communications (GSM) applications, radio communication, navigation, GPS (to 1.6 GHz), GSM, aeronautical mobile, UHF applications | 52.8 dB |
| 1.8 GHz | GSM applications, mobile personal communications, broadband, satellite, L-band (1 GHz to 2 GHz) | 61.0 dB |
| 2.4 GHz | 802.11b, 802.11g, 802.11n, Bluetooth®, mobile personal communications, industrial, scientific and medical (ISM) radio band, amateur radio and satellite, S-band (2 GHz to 4 GHz) | 69.5 dB |
| 3.6 GHz | Radiolocation, aero communication and navigation, satellite, mobile, S-band | 88.7 dB |
| 5 GHz | 802.11a, 802.11n, aero communication and navigation, mobile communication, space and satellite operation, C-band (4 GHz to 8 GHz) | 105.5 dB |

8.3.3 Phase Reversal Protection

The OPAx192-Q1 family has internal phase-reversal protection. Many op amps exhibit a phase reversal when the input is driven beyond its linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The OPAx192-Q1 is a rail-to-rail input op amp; therefore, the common-mode range can extend up to the rails. Input signals beyond the rails do not cause phase reversal; instead, the output limits into the appropriate rail. This performance is shown in Figure 53.

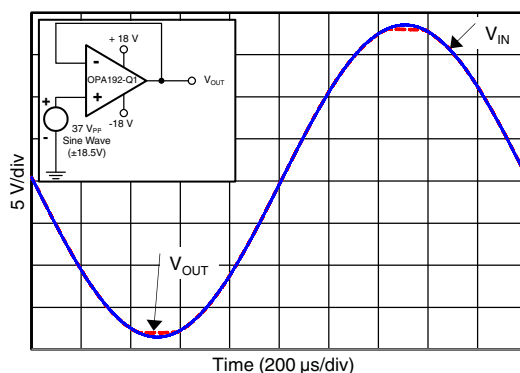
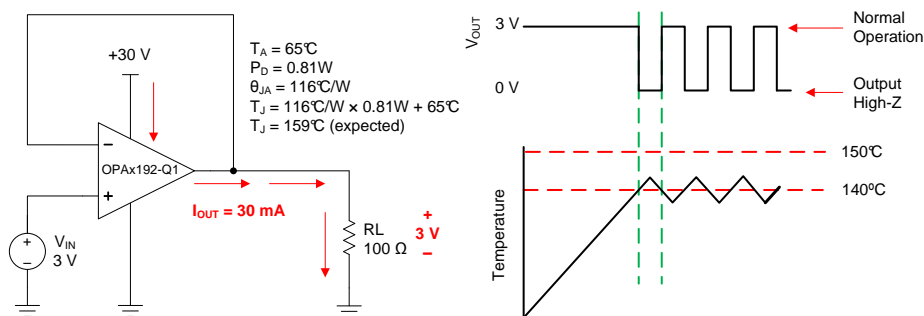


Figure 53. No Phase Reversal

8.3.4 Thermal Protection

The internal power dissipation of any amplifier causes its internal (junction) temperature to rise. This phenomenon is called *self heating*. The absolute maximum junction temperature of the OPAx192-Q1 is 150°C. Exceeding this temperature causes damage to the device. The OPAx192-Q1 has a thermal protection feature that prevents damage from self heating. The protection works by monitoring the temperature of the device and turning off the op amp output drive for temperatures above 140°C. Figure 54 shows an application example for the OPAx192-Q1 that has significant self heating (159°C) because of the power dissipation (0.81 W). Thermal calculations indicate that for an ambient temperature of 65°C the device junction temperature must reach 187°C. The actual device, however, turns off the output drive to maintain a safe junction temperature. Figure 54 shows how the circuit behaves during thermal protection. During normal operation, the device acts as a buffer so the output is 3 V. When self heating causes the device junction temperature to increase above 140°C, the thermal protection forces the output to a high-impedance state and the output is pulled to ground through resistor RL.



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Figure 54. Thermal Protection

8.3.5 Capacitive Load and Stability

The OPAx192-Q1 features a patented output stage capable of driving large capacitive loads, and in a unity-gain configuration, directly drives up to 1 nF of pure capacitive load. Increasing the gain enhances the ability of the amplifier to drive greater capacitive loads; see Figure 55 and Figure 56. The particular op amp circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether an amplifier is stable in operation.

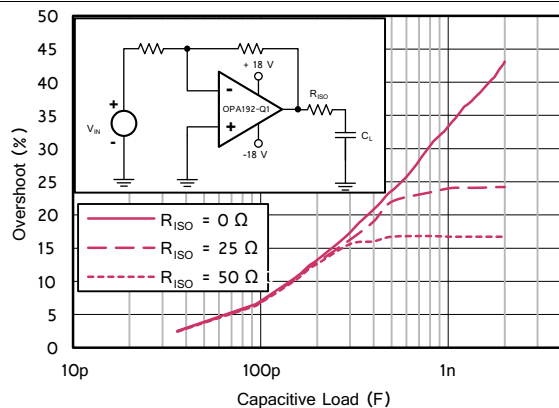


Figure 55. Small-Signal Overshoot vs Capacitive Load (100-mV Output Step)

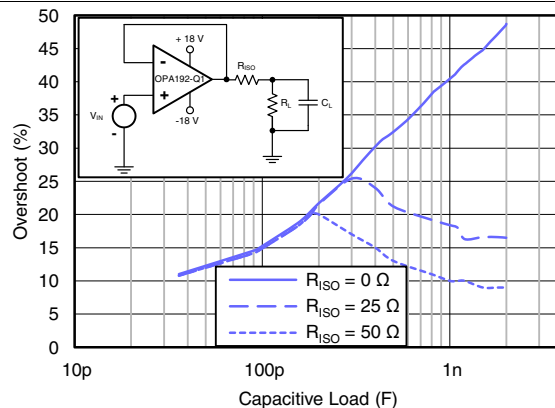


Figure 56. Small-Signal Overshoot vs Capacitive Load (100-mV Output Step)

For additional drive capability in unity-gain configurations, improve capacitive load drive by inserting a small (10 Ω to 20 Ω) resistor, R_{ISO} , in series with the output, as shown in [Figure 57](#). This resistor significantly reduces ringing and maintains dc performance for purely capacitive loads. However, if a resistive load is in parallel with the capacitive load, then a voltage divider is created, thus introducing a gain error at the output and slightly reducing the output swing. The error introduced is proportional to the ratio R_{ISO} / R_L , and is generally negligible at low output levels. A high capacitive-load drive makes the OPAx192-Q1 work well with applications such as reference buffers, MOSFET gate drives, and cable-shield drives. The circuit shown in [Figure 57](#) uses an isolation resistor, R_{ISO} , to stabilize the output of an op amp. R_{ISO} modifies the open-loop gain of the system for increased phase margin, and results using the OPAx192-Q1 are summarized in [Table 3](#). For additional information on techniques to optimize and design using this circuit, TI Precision Design [Capacitive Load Drive Solution using an Isolation Resistor](#) details complete design goals, simulation, and test results.

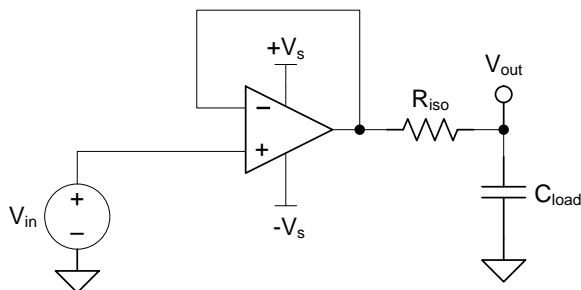


Figure 57. Extending Capacitive Load Drive with the OPAx192-Q1

Table 3. OPAx192-Q1 Capacitive Load Drive Solution Using Isolation Resistor Comparison of Calculated and Measured Results

| PARAMETER | VALUE | | | | | | | | | |
|------------------------|--------|-------|---------|-------|--------------|-------|-------------|-------|-----------|-------|
| Capacitive Load | 100 pF | | 1000 pF | | 0.01 μ F | | 0.1 μ F | | 1 μ F | |
| Phase Margin | 45° | 60° | 45° | 60° | 45° | 60° | 45° | 60° | 45° | 60° |
| R_{ISO} (Ω) | 47 | 360 | 24 | 100 | 20 | 51 | 6.2 | 15.8 | 2 | 4.7 |
| Measured Overshoot (%) | 23.2 | 8.6 | 10.4 | 22.5 | 9.0 | 22.1 | 8.7 | 23.1 | 8.6 | 21 |
| Calculated PM | 45.1° | 58.1° | 45.8° | 59.7° | 46.1° | 60.1° | 45.2° | 60.2° | 47.2° | 60.2° |



For step-by-step design procedure, circuit schematics, bill of materials, printed circuit board (PCB) files, simulation results, and test results, refer to [TI Precision Design TIDU032, Capacitive Load Drive Solution using an Isolation Resistor](#).

8.3.6 Common-Mode Voltage Range

The OPAx192-Q1 is a 36-V, true rail-to-rail input operational amplifier with an input common-mode range that extends 100 mV beyond either supply rail. This wide range is achieved with paralleled complementary N-channel and P-channel differential input pairs, as shown in Figure 58. The N-channel pair is active for input voltages close to the positive rail, typically $(V+) - 3\text{ V}$ to 100 mV above the positive supply. The P-channel pair is active for inputs from 100 mV below the negative supply to approximately $(V+) - 1.5\text{ V}$. There is a small transition region, typically $(V+) - 3\text{ V}$ to $(V+) - 1.5\text{ V}$ in which both input pairs are on. This transition region can vary modestly with process variation, and within this region PSRR, CMRR, offset voltage, offset drift, noise and THD performance may be degraded compared to operation outside this region.

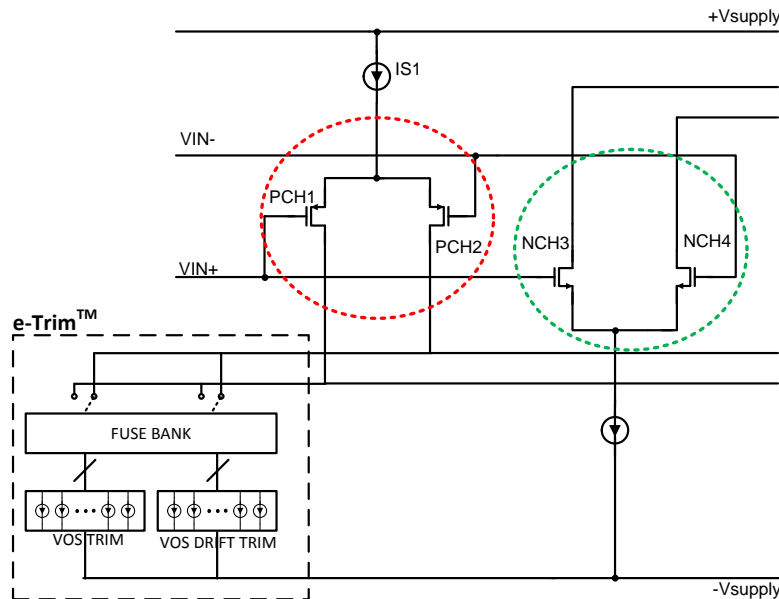


Figure 58. Rail-to-Rail Input Stage

To achieve the best performance for two-stage rail-to-rail input amplifiers, avoid the transition region when possible. The OPAx192-Q1 uses a precision trim for both the N-channel and P-channel regions. This technique enables significantly lower levels of offset than previous-generation devices, causing variance in the transition region of the input stages to appear exaggerated relative to offset over the full common-mode range, as shown in Figure 59.

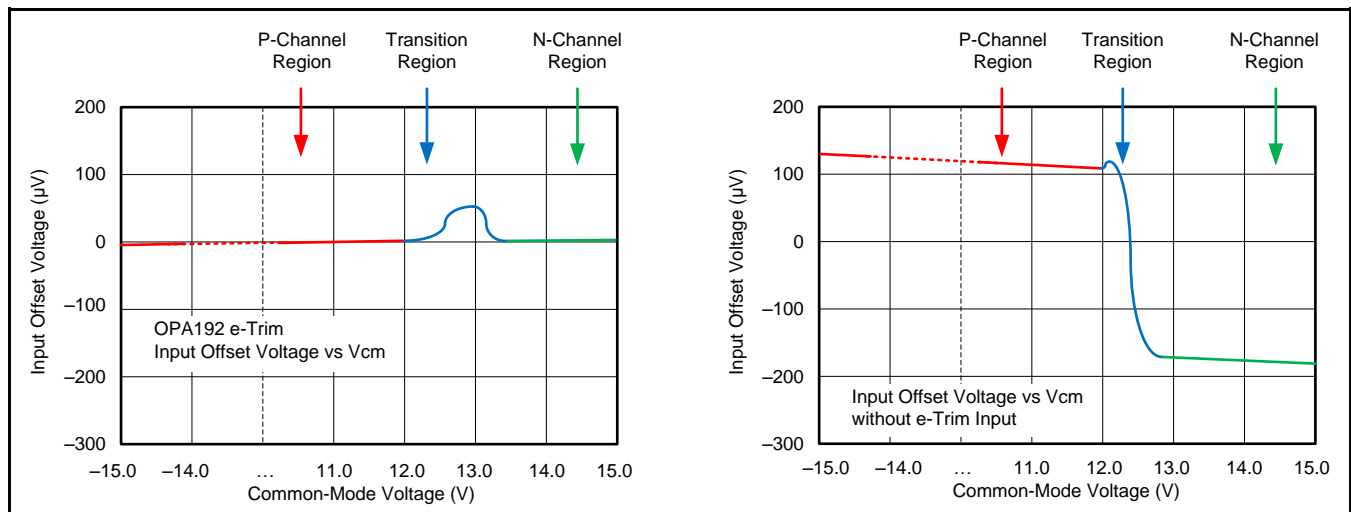
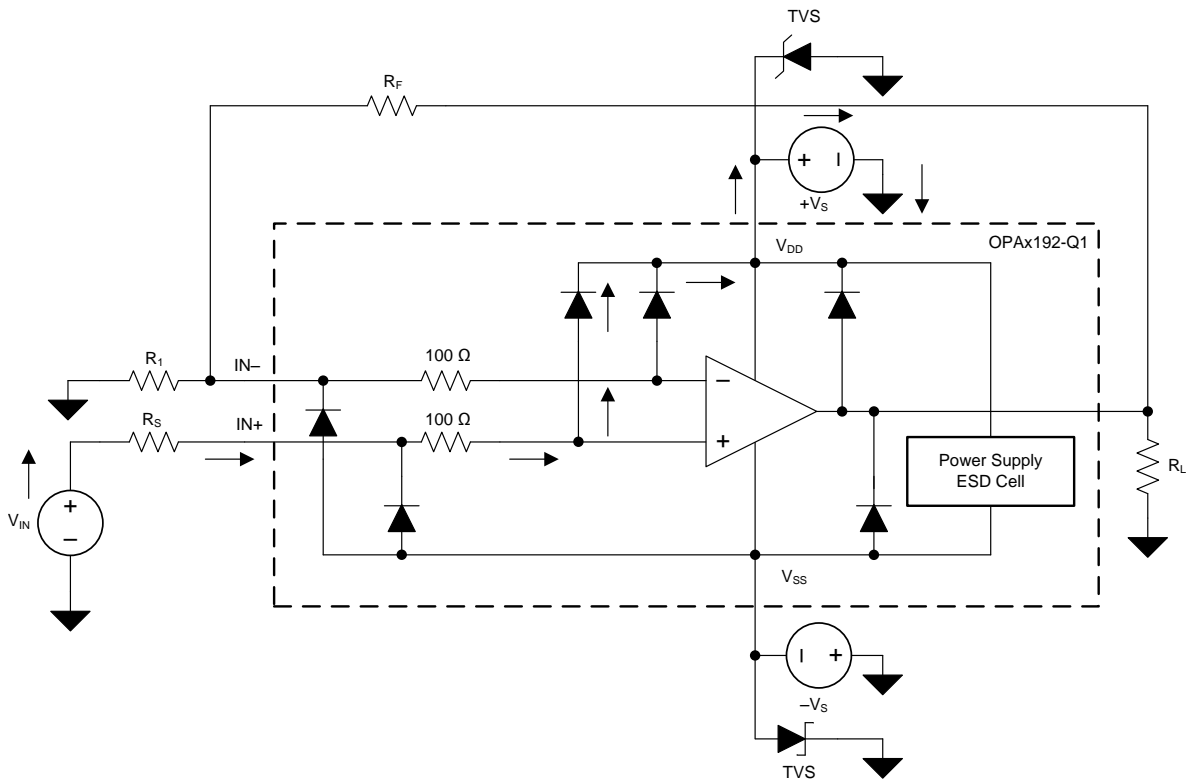


Figure 59. Common-Mode Transition vs Standard Rail-to-Rail Amplifiers

8.3.7 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress (EOS). These questions tend to focus on the device inputs, but may involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect them from accidental ESD events both before and during product assembly.

Having a good understanding of this basic ESD circuitry and its relevance to an electrical overstress event is helpful. Figure 60 shows an illustration of the ESD circuits contained in the OPAX192-Q1 (indicated by the dashed line area). The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power-supply lines, where the diodes meet at an absorption device or the power-supply ESD cell, internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.



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Figure 60. Equivalent Internal ESD Circuitry Relative to a Typical Circuit Application

An ESD event is very short in duration and very high voltage (for example, 1 kV, 100 ns), whereas an EOS event is long duration and lower voltage (for example, 50 V, 100 ms). The ESD diodes are designed for out-of-circuit ESD protection (that is, during assembly, test, and storage of the device before being soldered to the PCB). During an ESD event, the ESD signal is passed through the ESD steering diodes to an absorption circuit (labeled ESD power-supply circuit). The ESD absorption circuit clamps the supplies to a safe level.

Although this behavior is necessary for out-of-circuit protection, excessive current and damage is caused if activated in-circuit. A transient voltage suppressors (TVS) can be used to prevent against damage caused by turning on the ESD absorption circuit during an in-circuit ESD event. Using the appropriate current limiting resistors and TVS diodes allows for the use of device ESD diodes to protect against EOS events.

8.3.8 Overload Recovery

Overload recovery is defined as the time required for the op amp output to recover from a saturated state to a linear state. The output devices of the op amp enter a saturation region when the output voltage exceeds the rated operating voltage, either due to the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices require time to return back to the linear state. After the charge carriers return back to the linear state, the device begins to slew at the specified slew rate. Thus, the propagation delay in case of an overload condition is the sum of the overload recovery time and the slew time. The overload recovery time for the OPAx192-Q1 is approximately 200 ns.

8.4 Device Functional Modes

The OPAx192-Q1 has a single functional mode and is operational when the power-supply voltage is greater than 4.5 V (± 2.25 V). The maximum power supply voltage for the OPAx192-Q1 is 36 V (± 18 V).

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

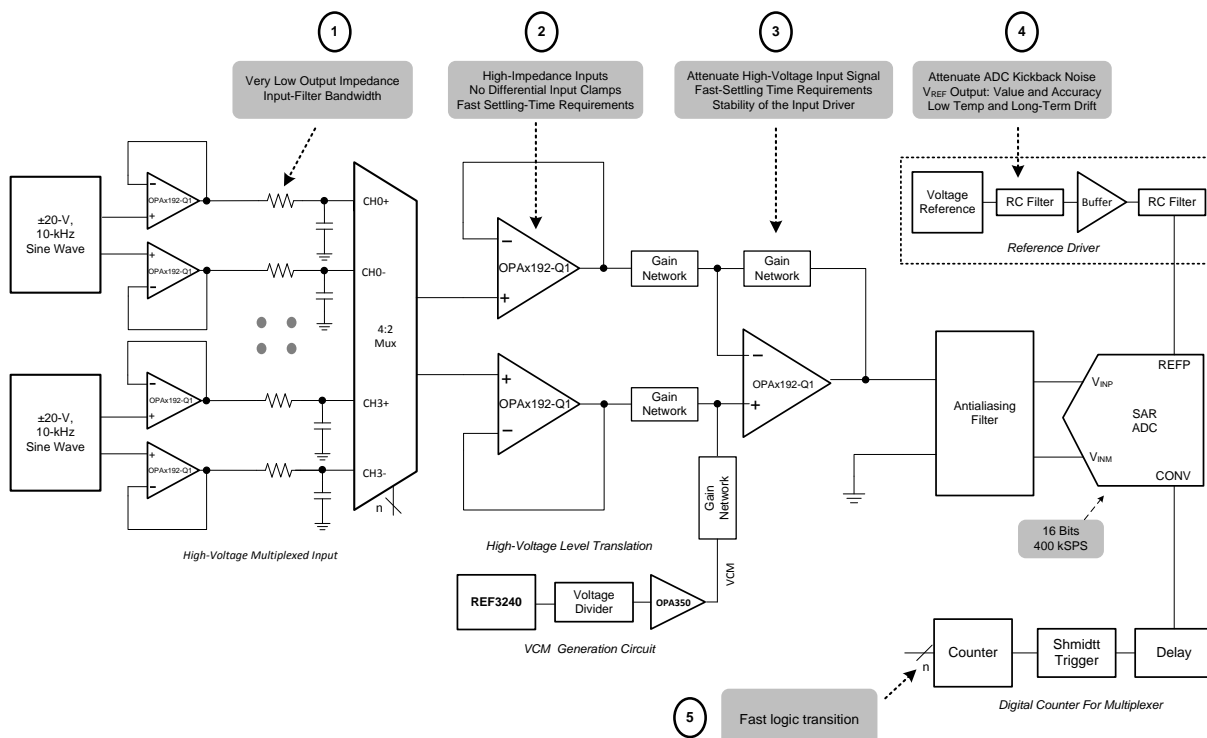
9.1 Application Information

The OPAx192-Q1 family offers outstanding dc precision and ac performance. These devices operate up to 36-V supply rails and offer true rail-to-rail input and output, ultra-low offset voltage and offset voltage drift, as well as 10-MHz bandwidth and high capacitive load drive. These features make the OPAx192-Q1 a robust, high-performance operational amplifier for high-voltage industrial applications.

9.2 Typical Applications

9.2.1 16-Bit Precision Multiplexed Data-Acquisition System

Figure 61 shows a 16-bit, differential, 4-channel, multiplexed data-acquisition system. This example is typical in industrial applications that require low distortion and a high-voltage differential input. The circuit uses the ADS8864, a 16-bit, 400-kSPS successive-approximation-resistor (SAR) analog-to-digital converter (ADC), along with a precision, high-voltage, signal-conditioning front end, and a 4-channel differential multiplexer (mux). This TI Precision Design details the process for optimizing the precision, high-voltage, front-end drive circuit using the OPAx192-Q1 and OPA140 to achieve excellent dynamic performance and linearity with the ADS8864.



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Figure 61. OPAx192-Q1 in 16-Bit, 400-kSPS, 4-Channel, Multiplexed Data Acquisition System for High-Voltage Inputs With Lowest Distortion

Typical Applications (continued)

9.2.1.1 Design Requirements

The primary objective is to design a ± 20 V, differential 4-channel multiplexed data acquisition system with lowest distortion using the 16-bit ADS8864 at a throughput of 400 kSPS for a 10 kHz full-scale pure sine-wave input. The design requirements for this block design are:

- System Supply Voltage: ± 15 V
- ADC Supply Voltage: 3.3 V
- ADC Sampling Rate: 400 kSPS
- ADC Reference Voltage (REFP): 4.096 V
- System Input Signal: A high-voltage differential input signal with a peak amplitude of 10 V and frequency (f_{IN}) of 10 kHz are applied to each differential input of the mux.

9.2.1.2 Detailed Design Procedure

The purpose of this precision design is to design an optimal high voltage multiplexed data acquisition system for highest system linearity and fast settling. The overall system block diagram is illustrated in [Figure 61](#). The circuit is a multichannel data acquisition signal chain consisting of an input low-pass filter, multiplexer (mux), mux output buffer, attenuating SAR ADC driver, digital counter for mux and the reference driver. The architecture allows fast sampling of multiple channels using a single ADC, providing a low-cost solution. The two primary design considerations to maximize the performance of a precision multiplexed data acquisition system are the mux input analog front-end and the high-voltage level translation SAR ADC driver design. However, carefully design each analog circuit block based on the ADC performance specifications in order to achieve the fastest settling at 16-bit resolution and lowest distortion system. The diagram includes the most important specifications for each individual analog block.

This design systematically approaches each analog circuit block to achieve a 16-bit settling for a full-scale input stage voltage and linearity for a 10-kHz sinusoidal input signal at each input channel. The first step in the design is to understand the requirement for extremely low impedance input-filter design for the mux. This understanding helps in the decision of an appropriate input filter and selection of a mux to meet the system settling requirements. The next important step is the design of the attenuating analog front-end (AFE) used to level translate the high-voltage input signal to a low-voltage ADC input when maintaining amplifier stability. The next step is to design a digital interface to switch the mux input channels with minimum delay. The final design challenge is to design a high-precision, reference-driver circuit that provides the required REFP reference voltage with low offset, drift, and noise contributions.

9.2.1.3 Application Curve

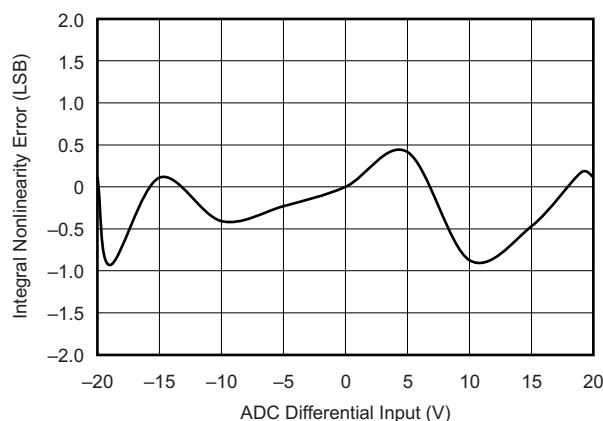


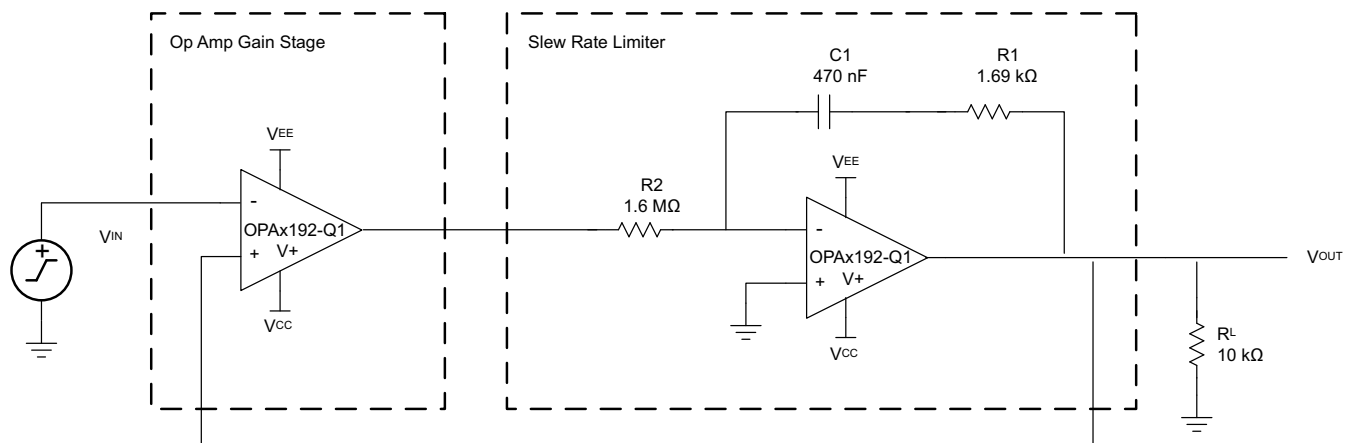
Figure 62. ADC 16-Bit Linearity Error for the Multiplexed Data Acquisition Block



For step-by-step design procedure, circuit schematics, bill of materials, PCB files, simulation results, and test results, refer to [TI Precision Design TIDU181, 16-bit, 400-kSPS, 4-Channel, Multiplexed Data Acquisition System for High Voltage Inputs with Lowest Distortion](#).

9.2.2 Slew Rate Limit for Input Protection

In control systems for valves or motors, abrupt changes in voltages or currents can cause mechanical damages. By controlling the slew rate of the command voltages into the drive circuits, the load voltages ramps up and down at a safe rate. For symmetrical slew-rate applications (positive slew rate equals negative slew rate), one additional op amp provides slew-rate control for a given analog gain stage. The unique input protection and high output current and slew rate of the OPAx192-Q1 make the device an optimal amplifier to achieve slew rate control for both dual- and single-supply systems. [Figure 63](#) shows the OPAx192-Q1 in a slew-rate limit design.



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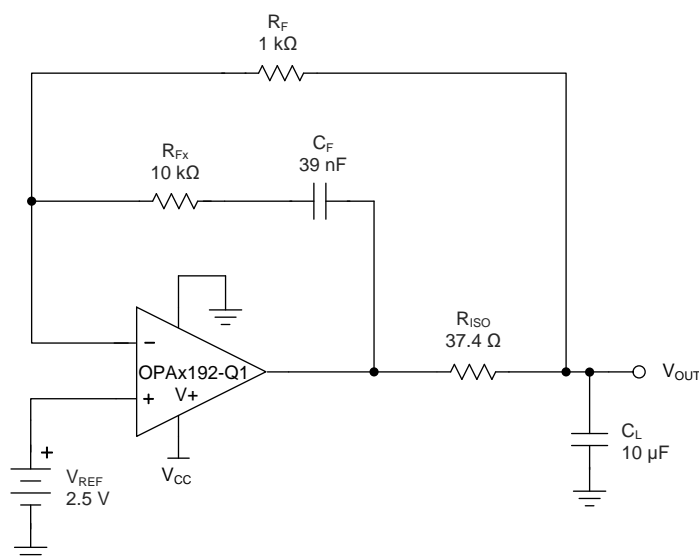
Figure 63. Slew Rate Limiter Uses One Op Amp



For step-by-step design procedure, circuit schematics, bill of materials, PCB files, simulation results, and test results, see [TI Precision Design TIDU026, Slew Rate Limiter Uses One Op Amp](#).

9.2.3 Precision Reference Buffer

The OPAx192-Q1 features high output current drive capability and low input offset voltage, making the device an excellent reference buffer to provide an accurate buffered output with ample drive current for transients. For the 10- μ F ceramic capacitor shown in Figure 64, R_{ISO} , a 37.4- Ω isolation resistor, provides separation of two feedback paths for optimal stability. Feedback path number one is through R_F and is directly at the output (V_{OUT}). Feedback path number two is through R_{FX} and C_F and is connected at the output of the op amp. The optimized stability components shown for the 10- μ F load give a closed-loop signal bandwidth at V_{OUT} of 4 kHz and still provides a loop gain phase margin of 89°. Any other load capacitances require recalculation of the stability components: R_F , R_{FX} , C_F , and R_{ISO} .



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Figure 64. Precision Reference Buffer

10 Power-Supply Recommendations

The OPAx192-Q1 is specified for operation from 4.5 V to 36 V (± 2.25 V to ± 18 V); many specifications apply from -40°C to $+125^{\circ}\text{C}$. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in [Typical Characteristics](#).

CAUTION

Supply voltages larger than 40 V can permanently damage the device; see [Absolute Maximum Ratings](#).

Place 0.1- μF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see [Layout](#).

11 Layout

11.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1- μF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds paying attention to the flow of the ground current. .
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As illustrated in [Figure 66](#), keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- Cleaning the PCB following board assembly is recommended for best performance.
- Any precision integrated circuit may experience performance shifts due to moisture ingress into the plastic package. Following any aqueous PCB cleaning process, TI recommends baking the PCB assembly to remove moisture introduced into the device packaging during the cleaning process. A low temperature, post cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

11.2 Layout Example

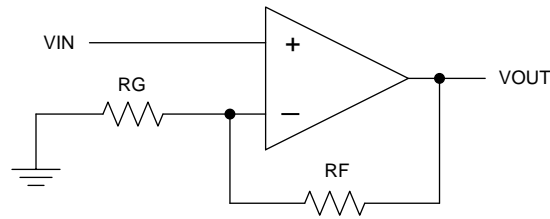
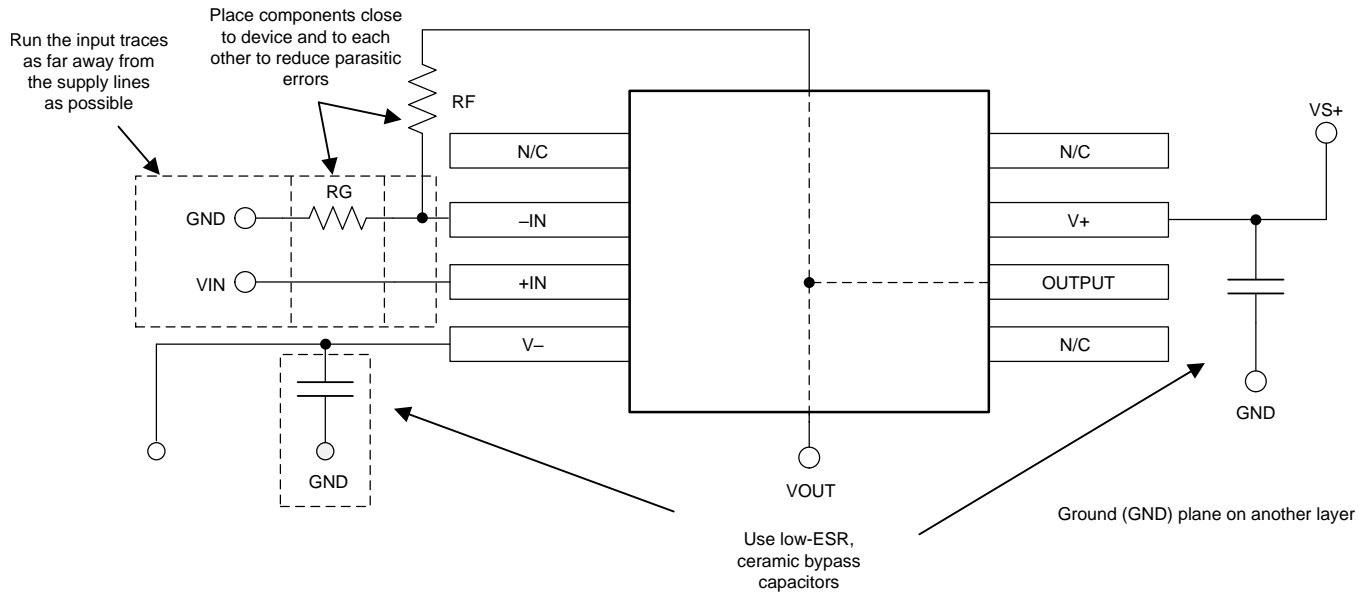


Figure 65. Schematic Representation



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Figure 66. Operational Amplifier Board Layout for Noninverting Configuration

12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

12.1.1.1 TINA-TI™ (Free Software Download)

TINA™ is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI is a free, fully-functional version of the TINA software, preloaded with a library of macro models in addition to a range of both passive and active models. TINA-TI provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a [free download](#) from the Analog eLab Design Center, TINA-TI offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

NOTE

These files require that either the TINA software (from DesignSoft™) or TINA-TI software be installed. Download the free TINA-TI software from the [TINA-TI folder](#).

12.1.1.2 TI Precision Designs

The OPA192 is featured in several Texas Instruments (TI) Precision Designs, available online at <http://www.ti.com/ww/en/analog/precision-designs/>. TI Precision Designs are analog solutions created by TI's precision analog applications experts and offer the theory of operation, component selection, simulation, complete PCB schematic and layout, bill of materials, and measured performance of many useful circuits.

12.2 Related Links

Table 4 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 4. Related Links

| PARTS | PRODUCT FOLDER | ORDER NOW | TECHNICAL DOCUMENTS | TOOLS & SOFTWARE | SUPPORT & COMMUNITY |
|------------|----------------------------|----------------------------|----------------------------|----------------------------|----------------------------|
| OPA192-Q1 | Click here | Click here | Click here | Click here | Click here |
| OPA2192-Q1 | Click here | Click here | Click here | Click here | Click here |

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.5 Trademarks

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12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| OPA192QDGKRQ1 | ACTIVE | VSSOP | DGK | 8 | 2500 | RoHS & Green | NIPDAUAG | Level-2-260C-1 YEAR | -40 to 125 | 192 | Samples |
| OPA2192QDGKRQ1 | ACTIVE | VSSOP | DGK | 8 | 2500 | RoHS & Green | NIPDAUAG | Level-2-260C-1 YEAR | -40 to 125 | 2192 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF OPA192-Q1, OPA2192-Q1 :

- Catalog: [OPA192](#), [OPA2192](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| OPA192QDGKRQ1 | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| OPA2192QDGKRQ1 | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS

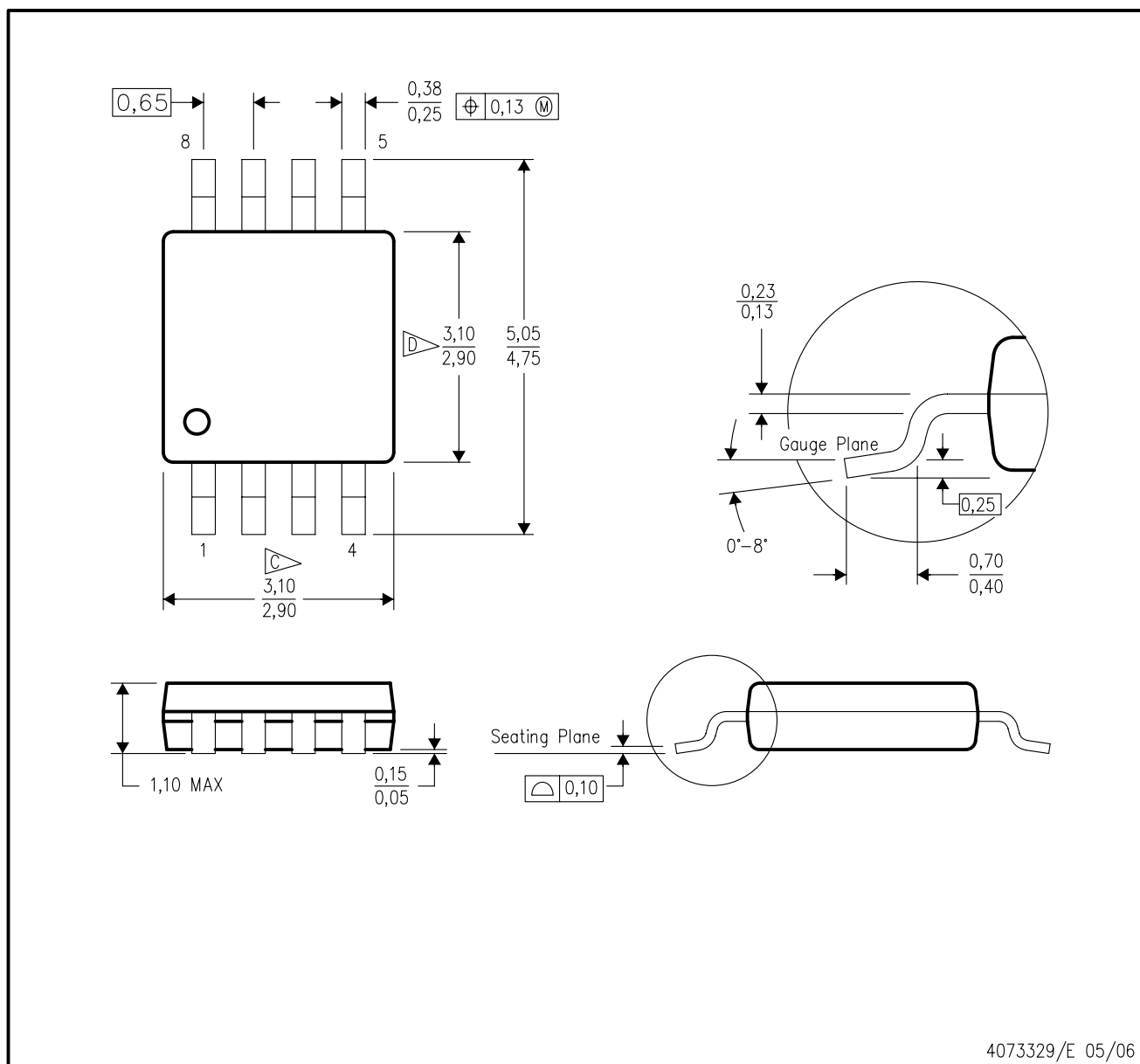


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| OPA192QDGKRQ1 | VSSOP | DGK | 8 | 2500 | 366.0 | 364.0 | 50.0 |
| OPA2192QDGKRQ1 | VSSOP | DGK | 8 | 2500 | 366.0 | 364.0 | 50.0 |

DGK (S-PDSO-G8)

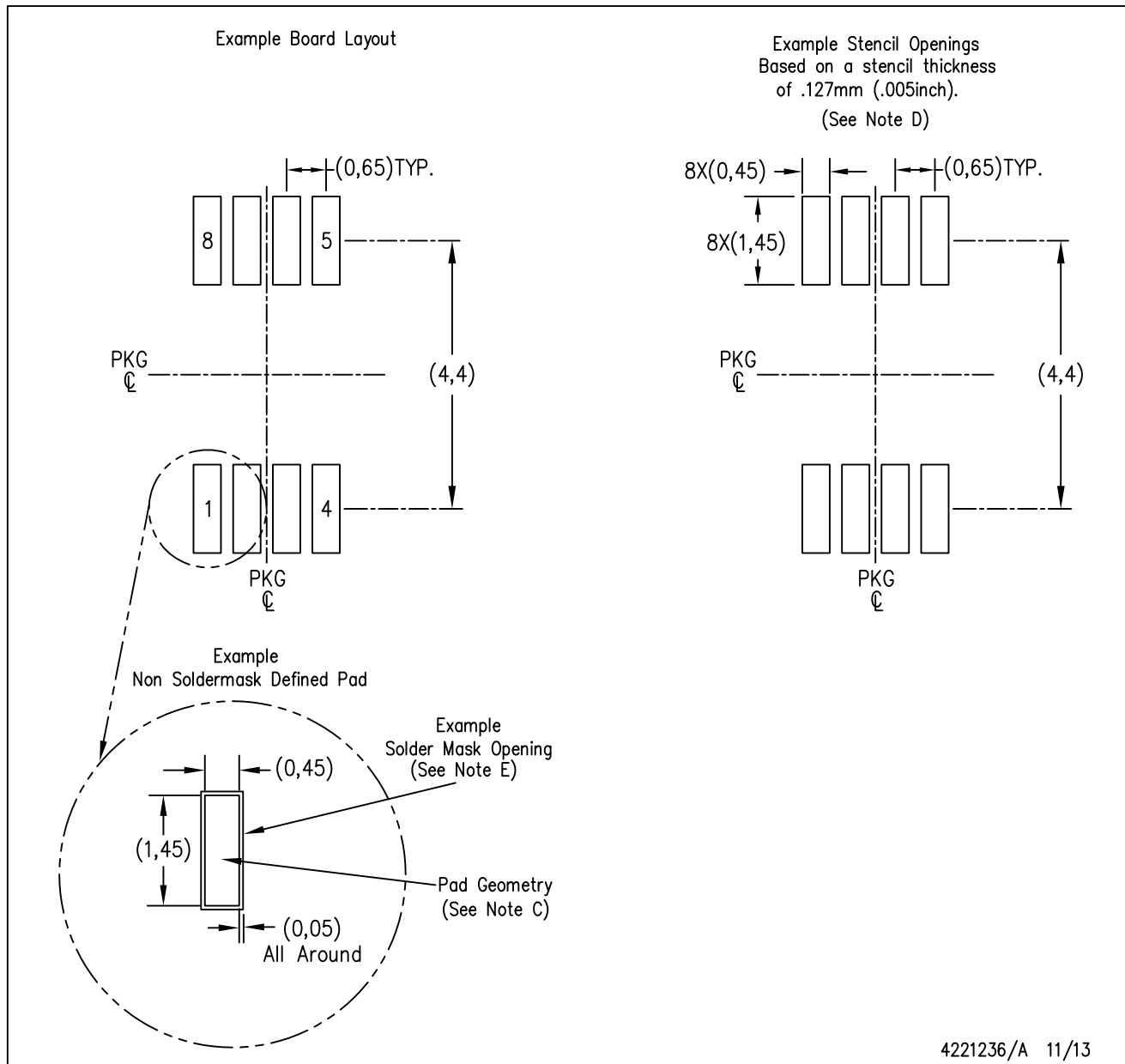
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
 - E. Falls within JEDEC MO-187 variation AA, except interlead flash.

DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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